



**THE DATASHEET OF
TRF3702IRHCR**



1.5 GHz to 2.5 GHz QUADRATURE MODULATOR

FEATURES

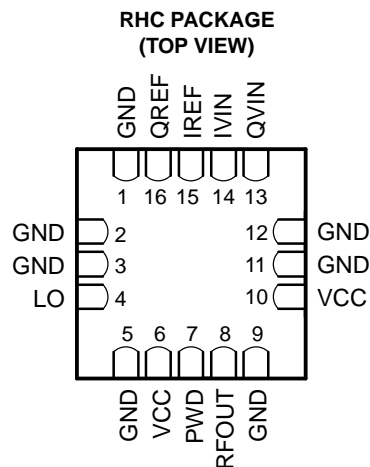
- 71 dBc Single-Carrier WCDMA ACPR at –14-dBm Channel Power
- P1dB of 7 dBm
- Typical Unadjusted Carrier Suppression 35 dBc at 2 GHz
- Typical Unadjusted Sideband Suppression 35 dBc at 2 GHz
- Very Low Noise Floor
- Differential or Single-Ended I, Q Inputs
- Convenient Single-Ended LO Input
- Silicon Germanium Technology

APPLICATIONS

- Cellular Base Transceiver Station Transmit Channel
- IF Sampling Applications
- TDMA: GSM, IS-136, EDGE/UWC-136
- CDMA: IS-95, UMTS, CDMA2000
- Wireless Local Loop
- Wireless LAN IEEE 802.11
- LMDS, MMDS
- Wideband Transceivers

DESCRIPTION

The TRF3702 is an ultralow-noise direct quadrature modulator that is capable of converting complex input signals from baseband or IF directly up to RF. An internal analog combiner sums the real and imaginary components of the RF outputs. This combined output can feed the RF preamp at frequencies of up to 2.5 GHz. The modulator is implemented as a double-balanced mixer. An internal local oscillator (LO) phase splitter accommodates a single-ended LO input, eliminating the need for a costly external balun.



P0003-01



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



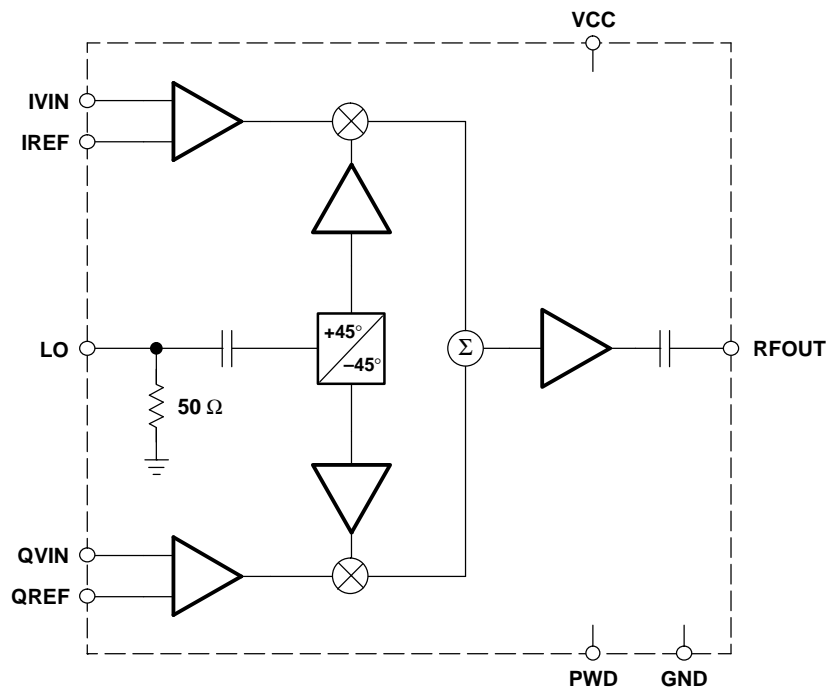
This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

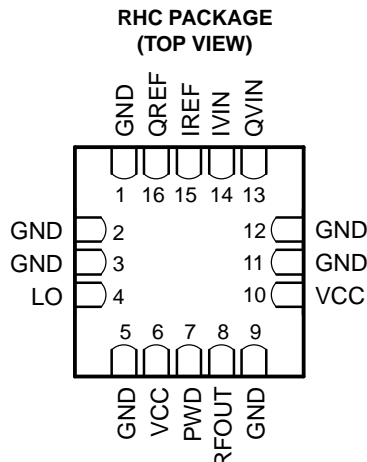
AVAILABLE OPTIONS

| | |
|---------------|--------------------------------------|
| T_A | 4-mm × 4-mm 16-Pin RHC (QFN) Package |
| -40°C to 85°C | TRF3702IRHC |
| | TRF3702IRHCR (Tape and reel) |

FUNCTIONAL BLOCK DIAGRAM



B0002-01



P0003-01

TERMINAL FUNCTIONS

| TERMINAL | | I/O | DESCRIPTION |
|----------|-----------------------|-----|---|
| NAME | NO. | | |
| GND | 1, 2, 3, 5, 9, 11, 12 | | Ground |
| IREF | 15 | I | In-phase (I) reference voltage/differential input |
| IVIN | 14 | I | In-phase (I) signal input |
| LO | 4 | I | Local oscillator input |
| PWD | 7 | I | Power down |
| QREF | 16 | I | Quadrature (Q) reference voltage/differential input |
| QVIN | 13 | I | Quadrature (Q) signal input |
| RFOUT | 8 | O | RF output |
| VCC | 6, 10 | | Supply voltage |

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾⁽²⁾

| | | |
|----------|---|--------------------|
| V_{CC} | Supply voltage range | –0.5 V to 6 V |
| | LO input power level | 10 dBm |
| | Baseband input voltage level (single-ended) | 3 V _{p-p} |
| T_A | Operating free-air temperature range | –40°C to 85°C |
| | Lead temperature for 10 seconds | 260°C |

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Measured with respect to ground

RECOMMENDED OPERATING CONDITIONS

| | MIN | NOM | MAX | UNIT |
|--|------|------|-----|------|
| Supplies and References | | | | |
| V _{CC} Analog supply voltage | 4.5 | 5 | 5.5 | V |
| VCM (IVIN, QVIN, IREF, QREF input common-mode voltage) | 3.7 | | | V |
| Local Oscillator (LO) Input | | | | |
| Input frequency | 1500 | 2500 | | MHz |
| Power level (measured into 50 Ω) | –6 | 0 | 6 | dBm |
| Signal Inputs (IVIN, QVIN) | | | | |
| Input bandwidth | 700 | | | MHz |

ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, V_{CC} = 5 V, VCM = 3.7 V, f_{LO} = 2140 MHz at 0 dBm, T_A = 25°C (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|---|-----|---------|-----|------|
| Power Supply | | | | | |
| I _{CC} Total supply current | V(PWD) = 5 V | | 145 | 170 | mA |
| | V(PWD) = 0 V | | 13 | 30 | |
| Turnon time | | | 120 | | ns |
| Turnoff time | | | 20 | | ns |
| Power-down input impedance | | | 11 | | kΩ |
| Local Oscillator (LO) Input | | | | | |
| Input impedance ⁽¹⁾ | | | 27 + j8 | | Ω |
| Signal Inputs (IVIN, QVIN, IREF, QREF) | | | | | |
| Input bias current | I, Q = VCM = 3.7 V (all inputs tied to VCM) | | 16 | | μA |
| Input impedance | Single-ended input | | 260 | | kΩ |
| | Differential input | | 130 | | |

(1) For a listing of impedances at various frequencies, see Table 1.

Table 1. RFOUT and LO Pin Impedance

| Frequency (MHz) | Z (RFOUT Pin) | Z (LO Pin) |
|-----------------|---------------|---------------|
| 1500 | 31 – j 4.7 | 31.7 – j 8.8 |
| 1600 | 30.9 – j 0.3 | 29.3 – j 6.2 |
| 1700 | 29.3 + j 3.1 | 27.3 – j 3.1 |
| 1800 | 27.9 + j 7.2 | 26.5 – j 0.17 |
| 1900 | 27.6 + j 13 | 26.1+ – j 2.7 |
| 2000 | 29.4 + j 19.8 | 26.5 + j 5.4 |
| 2100 | 34.6 + j 27.2 | 27 + j 7.6 |
| 2200 | 44.2 + j 33 | 28 + j 9.5 |
| 2300 | 60 + j 33.6 | 29 + j 10.6 |
| 2400 | 78 + j 21 | 29.5 + j 11 |
| 2500 | 82 – j 5.8 | 29.8 + j 12.2 |

RF OUTPUT PERFORMANCE

Over recommended operating conditions, VCC = 5 V, VCM = 3.7 V, f_{LO} = 1842 MHz at 0 dBm (unless otherwise specified)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|--|-----|---------|-----------------------|--------|
| Single and Two-Tone Specifications | | | | | |
| Output power | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz | -5 | -2.5 | | dBm |
| Second baseband harmonic (USB or LSB) ⁽²⁾ | | | -50 | -42 | dBc |
| Third baseband harmonic (USB or LSB) ⁽²⁾ | | | -57 | -50 | dBc |
| IMD ₃ | I, Q ⁽¹⁾ = 1 Vp-p (two-tone signal, f _{BB1} = 928 kHz, f _{BB2} = 992 kHz) | | -59 | -53 | dBc |
| P1dB (output compression point) | | | 7 | | dBm |
| NSD Noise spectral density | I, Q = VCM = 3.7 VDC (all inputs tied to VCM), 6-MHz offset from carrier | | -155 | | dBm/Hz |
| | 6-MHz offset from carrier, P _{out} = 0 dBm, over temperature | | -148.5 | -146.5 ⁽³⁾ | |
| RFOUT pin impedance ⁽⁴⁾ | | | 28 + j8 | | Ω |
| Carrier suppression | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz, unadjusted | | 30 | | dBc |
| | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz, optimized | | 55 | | |
| | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz, over temperature ⁽⁵⁾ | | 44 | | |
| Sideband suppression | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz, unadjusted | | 35 | | dBc |
| | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz, optimized | | 55 | | |
| | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz, over temperature ⁽⁵⁾ | | 47 | | |

(1) I, Q = 1 Vp-p implies that the magnitude of the signal at each input pin IVIN, IREF, QVIN, QREF is equal to 500 mVp-p.

(2) USB = upper sideband. LSB = lower sideband.

(3) Maximum noise values are assured by statistical characterization only, not production testing. The values specified are over the entire temperature range, T_A = -40°C to 85°C.

(4) For a listing of impedances at various frequencies, see Table 1.

(5) After optimization at room temperature. See the *Definitions of Selected Specifications* section.

RF OUTPUT PERFORMANCE

Over recommended operating conditions, VCC = 5 V, VCM = 3.7 V, f_{LO} = 1960 MHz at 0 dBm (unless otherwise specified)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|--|-----|----------|-----------------------|--------|
| Single and Two-Tone Specifications | | | | | |
| Output power | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz | | -3 | | dBm |
| Second baseband harmonic (USB or LSB) ⁽²⁾ | | | -50 | | dBc |
| Third baseband harmonic (USB or LSB) ⁽²⁾ | | | -60 | | dBc |
| IMD ₃ | I, Q ⁽¹⁾ = 1 Vp-p (two-tone signal, f _{BB1} = 928 kHz, f _{BB2} = 992 kHz) | | -59 | -53 | dBc |
| P1dB (output compression point) | | | 7 | | dBm |
| NSD Noise spectral density | 6-MHz offset from carrier, P _{out} = 0 dBm, over temperature | | -148 | -146.5 ⁽³⁾ | dBm/Hz |
| RFOUT pin impedance ⁽⁴⁾ | | | 28 + j15 | | Ω |
| Carrier suppression | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz, unadjusted | | 33 | | dBc |
| | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz, optimized | | 55 | | |
| Sideband suppression | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz, unadjusted | | 35 | | dBc |
| | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz, optimized | | 55 | | |

(1) I, Q = 1 Vp-p implies that the magnitude of the signal at each input pin IVIN, IREF, QVIN, QREF is equal to 500 mVp-p.

(2) USB = upper sideband. LSB = lower sideband.

(3) Maximum noise values are assured by statistical characterization only, not production testing. The values specified are over the entire temperature range, T_A = -40°C to 85°C.

(4) For a listing of impedances at various frequencies, see Table 1.

RF OUTPUT PERFORMANCE

Over recommended operating conditions, VCC = 5 V, VCM = 3.7 V, f_{LO} = 2.1 GHz at 0 dBm (unless otherwise specified)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|---|-----|----------|-----------------------|--------|
| Single and Two-Tone Specifications | | | | | |
| Output power | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz | -5 | -3 | | dBm |
| Second baseband harmonic (USB or LSB) ⁽²⁾ | | | -50 | -42 | dBc |
| Third baseband harmonic (USB or LSB) ⁽²⁾ | | | -60 | -51 | dBc |
| IMD ₃ | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz (two-tone signal, f _{BB1} = 928 kHz, f _{BB2} = 992 kHz) | | -55 | -47 | dBc |
| P1dB (output compression point) | | | 7 | | dBm |
| NSD Noise spectral density | 60-MHz offset from carrier, P _{out} = 0 dBm, over temperature | | -151 | -148.5 ⁽³⁾ | dBm/Hz |
| WCDMA ACPR | Single carrier, channel power = -14 dBm | | 71 | | dBc |
| RFOUT pin impedance ⁽⁴⁾ | | | 35 + j27 | | Ω |
| Carrier suppression | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz, unadjusted | | 30 | | dBc |
| | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz, optimized | | 55 | | |
| | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz, over temperature ⁽⁵⁾ | | 47 | | |
| Sideband suppression | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz, unadjusted | | 37 | | dBc |
| | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz, optimized | | 55 | | |
| | I, Q ⁽¹⁾ = 1 Vp-p, f _{BB} = 928 kHz, over temperature ⁽⁵⁾ | | 47 | | |

(1) I, Q = 1 Vp-p implies that the magnitude of the signal at each input pin IVIN, IREF, QVIN, QREF is equal to 500 mVp-p.

(2) USB = upper sideband. LSB = lower sideband.

(3) Maximum noise values are assured by statistical characterization only, not production testing. The values specified are over the entire temperature range, T_A = -40°C to 85°C.

(4) For a listing of impedances at various frequencies, see Table 1.

(5) After optimization at room temperature. See the *Definitions of Selected Specifications* section.

THERMAL CHARACTERISTICS

| PARAMETER | CONDITION | NOM | UNIT |
|---|--|------|------|
| R _{θJA} Thermal resistance, junction to ambient | Soldered pad using four-layer JEDEC board with four thermal vias | 42.8 | °C/W |
| R _{θJM} Thermal resistance, junction to mounting surface | | 24.8 | °C/W |
| R _{θJC} Thermal resistance, junction to case | Soldered pad using two-layer JEDEC board with four thermal vias | 67.6 | °C/W |

DEFINITIONS OF SELECTED SPECIFICATIONS

Unadjusted Carrier Suppression

This specification measures the amount by which the local oscillator component is attenuated in the output spectrum of the modulator relative to the carrier. It is assumed that the baseband inputs delivered to the pins of the TRF3702 are perfectly matched to have the same dc offset (VCM). This includes all four baseband inputs: IVIN, QVIN, IREF and QREF. Unadjusted carrier suppression is measured in dBc.

Adjusted (Optimized) Carrier Suppression

This differs from the unadjusted suppression number in that the dc offsets of the baseband inputs are iteratively adjusted around their theoretical value of VCM to yield the maximum suppression of the LO component in the output spectrum. Adjusted carrier suppression is measured in dBc.

DEFINITIONS OF SELECTED SPECIFICATIONS (continued)

Unadjusted Sideband Suppression

This specification measures the amount by which the unwanted sideband of the input signal is attenuated in the output of the modulator, relative to the wanted sideband. It is assumed that the baseband inputs delivered to the modulator input pins are perfectly matched in amplitude and are exactly 90° out of phase. Unadjusted sideband suppression is measured in dBc.

Adjusted (Optimized) Sideband Suppression

This differs from the unadjusted sideband suppression in that the baseband inputs are iteratively adjusted around their theoretical values to maximize the amount of sideband suppression. Adjusted sideband suppression is measured in dBc.

Suppressions Over Temperature

This specification assumes that the user has gone through the optimization process for the suppression in question, and set the optimal settings for the I, Q inputs at $T_A = 25^\circ\text{C}$. This specification then measures the suppression when temperature conditions change after the initial calibration is done.

Figure 1 shows a simulated output and illustrates the respective definitions of various terms used in this data sheet. The graph assumes a baseband input of 50 kHz.

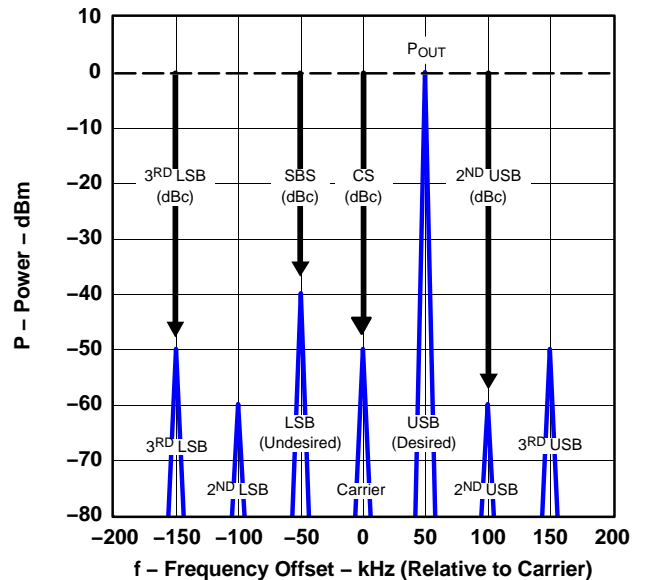


Figure 1. Graphical Illustration of Common Terms

TYPICAL CHARACTERISTICS

For all the performance plots in this section, the following conditions were used, unless otherwise noted: VCC = 5 V, VCM = 3.7 V, P_{LO} = 0 dBm, I and Q inputs driven differentially at a frequency of 50 kHz. In the case of optimized suppressions, the point of optimization is noted and is always at nominal conditions and room temperature. A level of >50 dBc is assumed to be optimized.

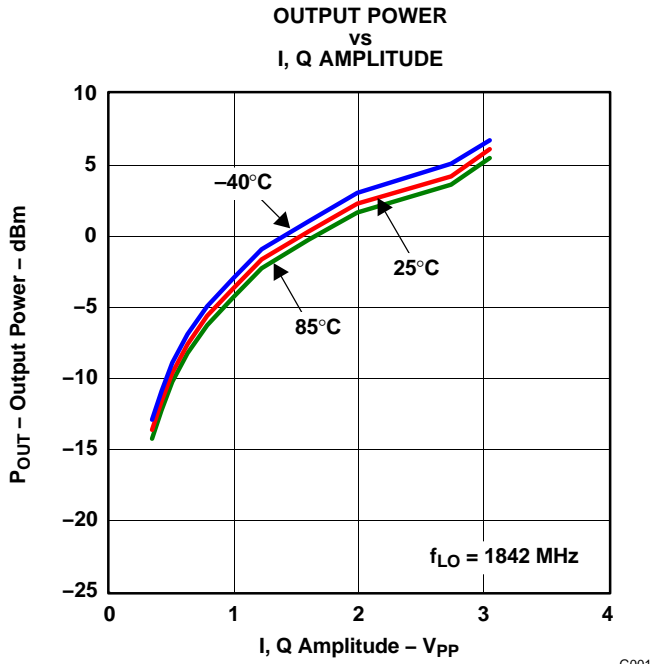


Figure 2.

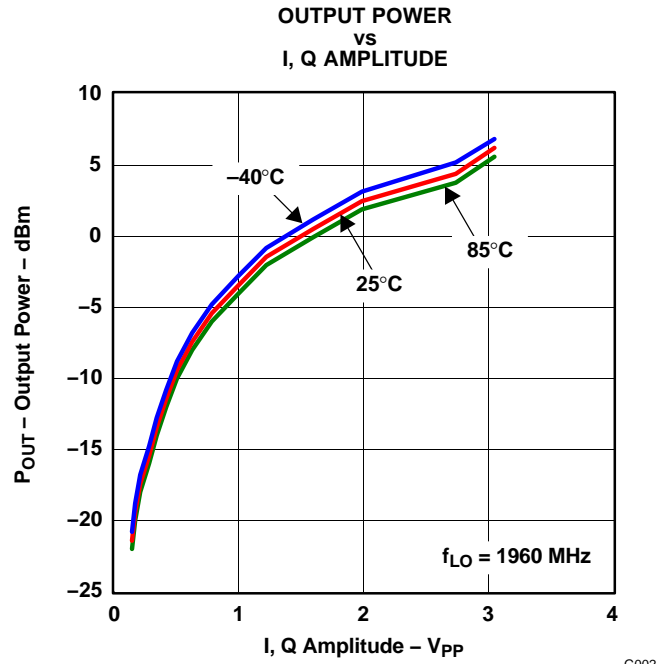


Figure 3.

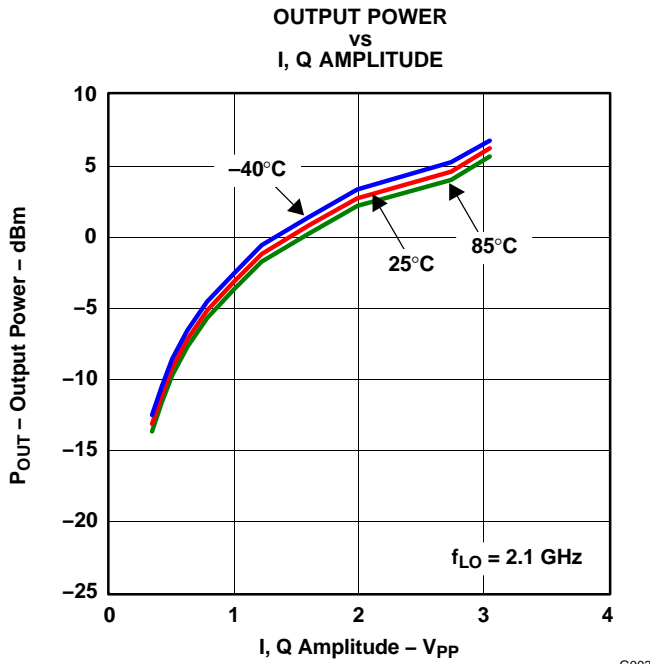


Figure 4.

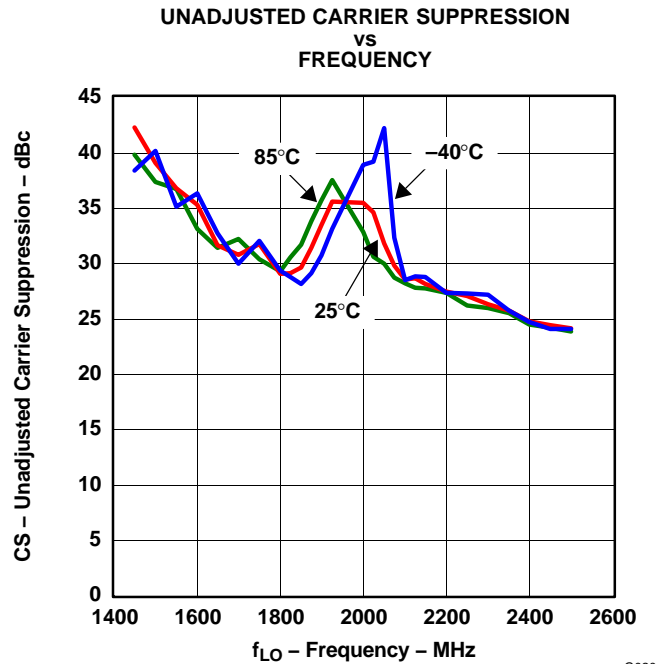
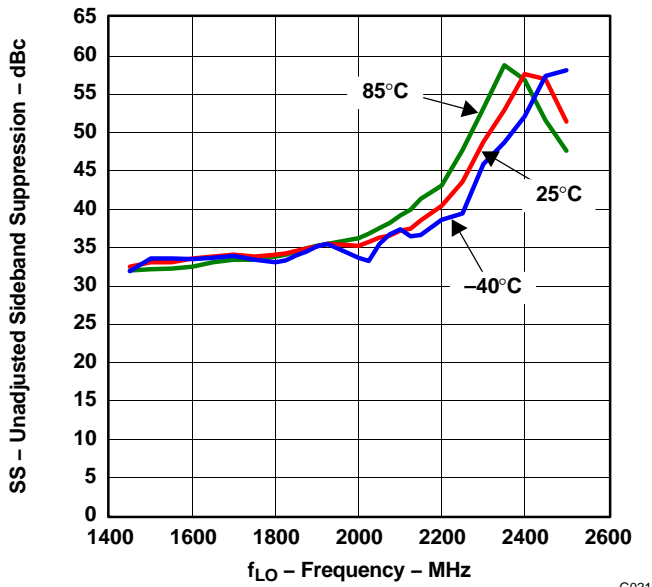


Figure 5.

TYPICAL CHARACTERISTICS (continued)

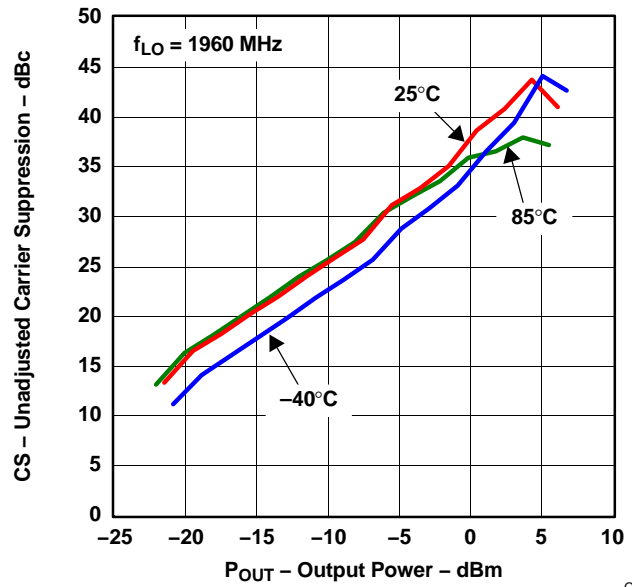
UNADJUSTED SIDEBAND SUPPRESSION
vs
FREQUENCY



G021

Figure 6.

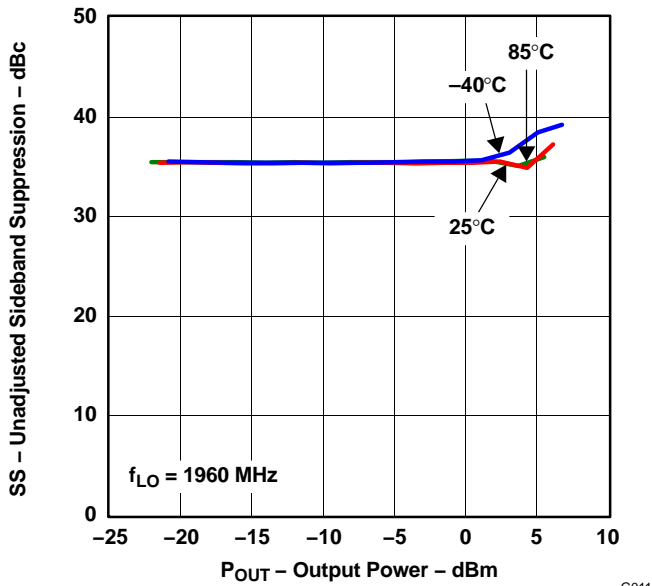
UNADJUSTED CARRIER SUPPRESSION
vs
OUTPUT POWER



G008

Figure 7.

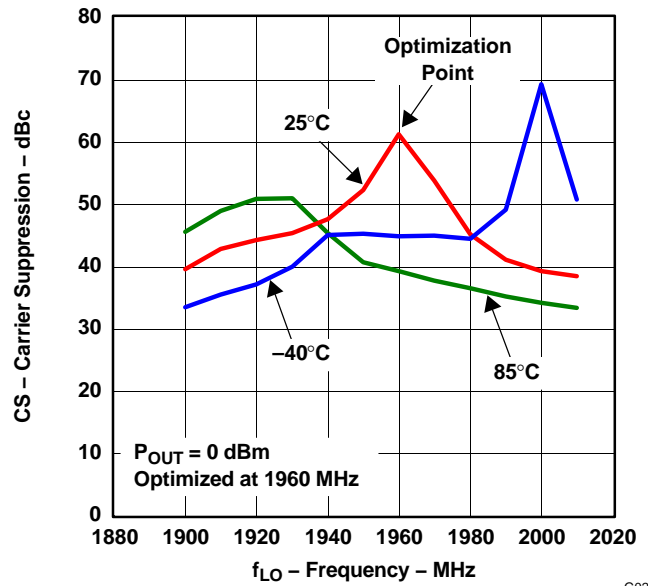
UNADJUSTED SIDEBAND SUPPRESSION
vs
OUTPUT POWER



G011

Figure 8.

CARRIER SUPPRESSION
vs
FREQUENCY



G025

Figure 9.

TYPICAL CHARACTERISTICS (continued)

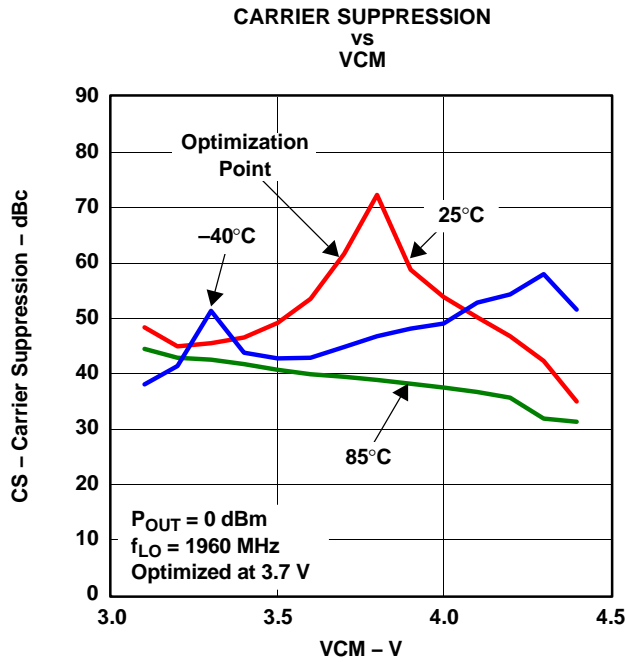


Figure 10.

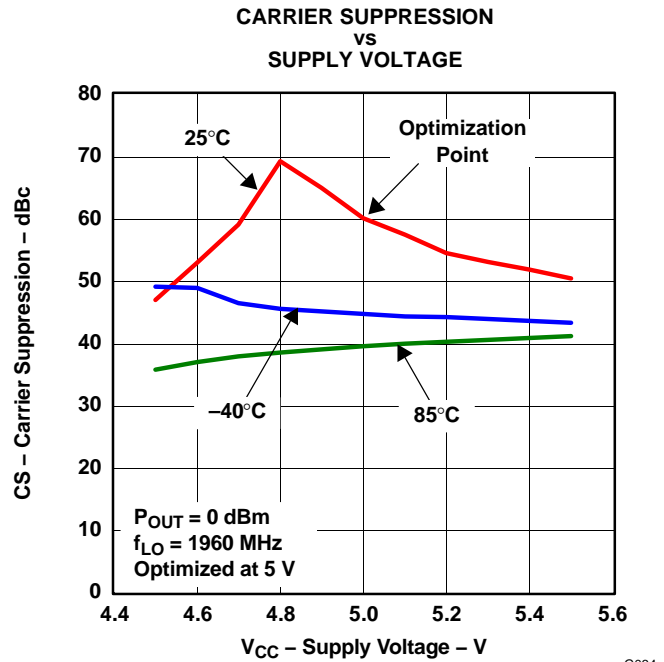


Figure 11.

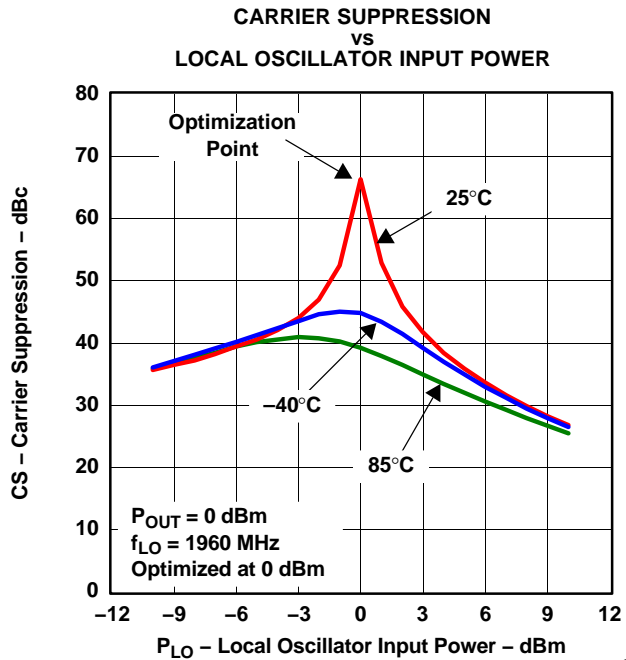


Figure 12.

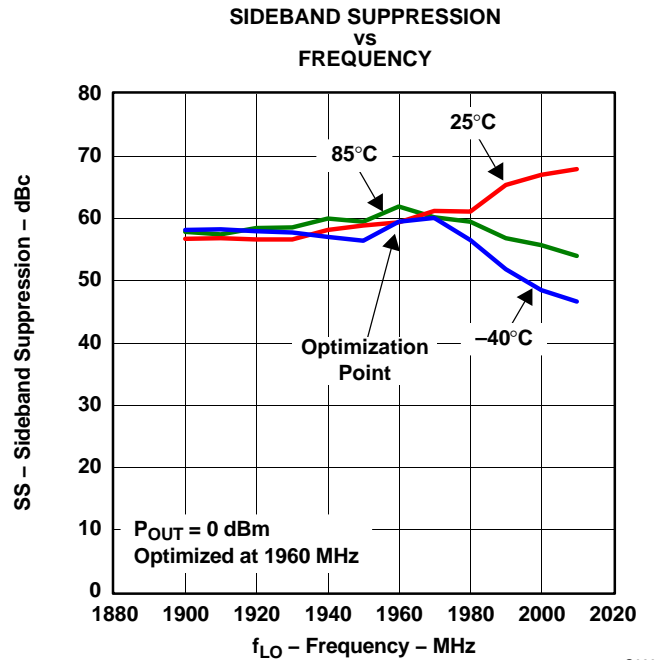


Figure 13.

TYPICAL CHARACTERISTICS (continued)

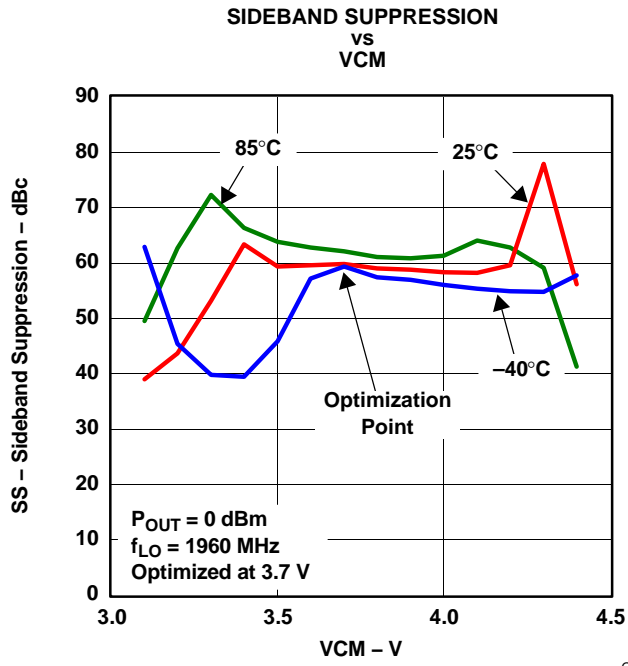


Figure 14.

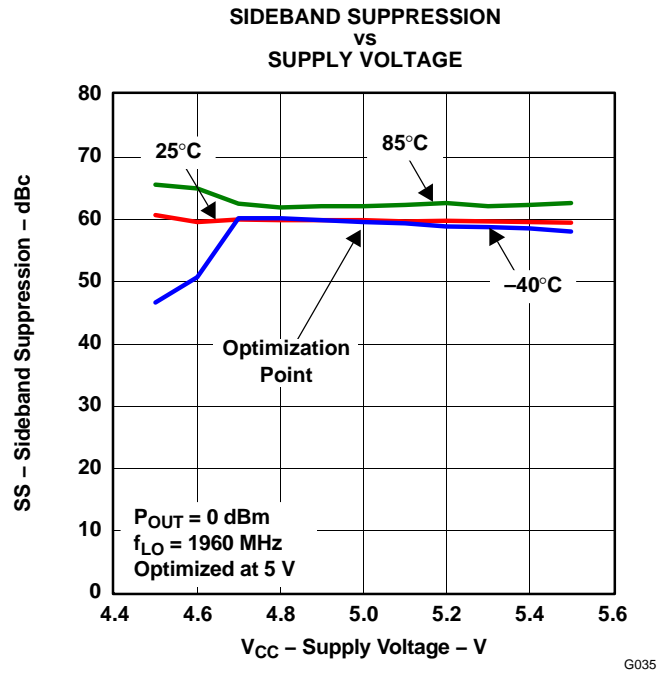


Figure 15.

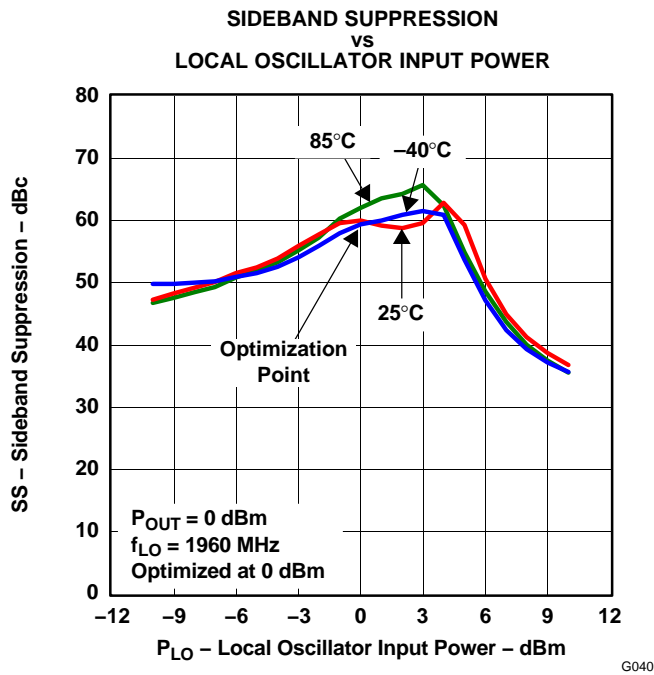


Figure 16.

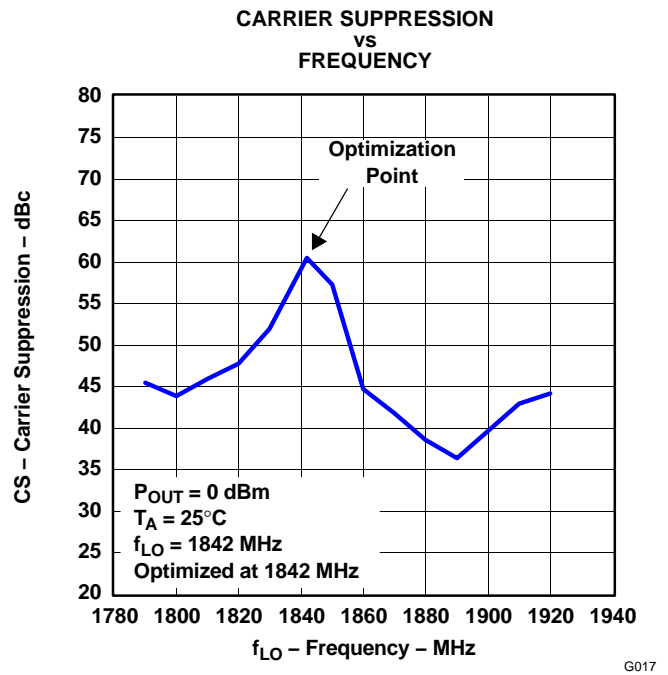


Figure 17.

TYPICAL CHARACTERISTICS (continued)

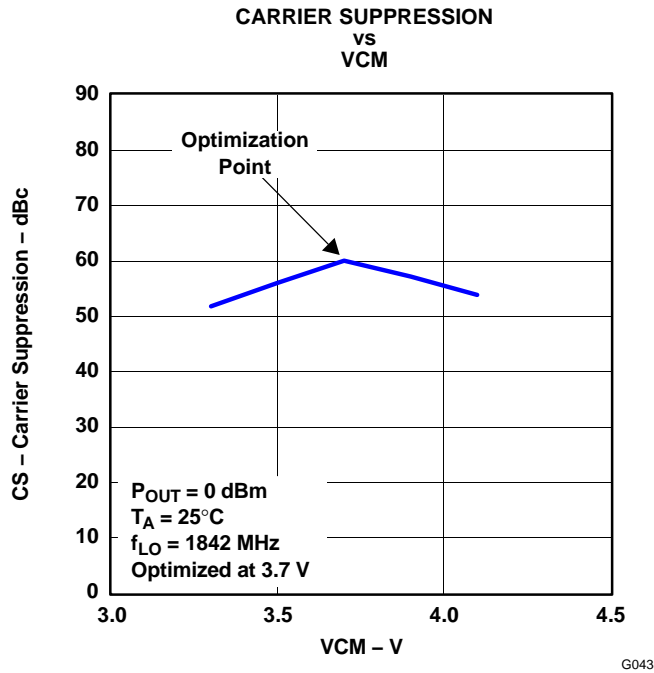


Figure 18.

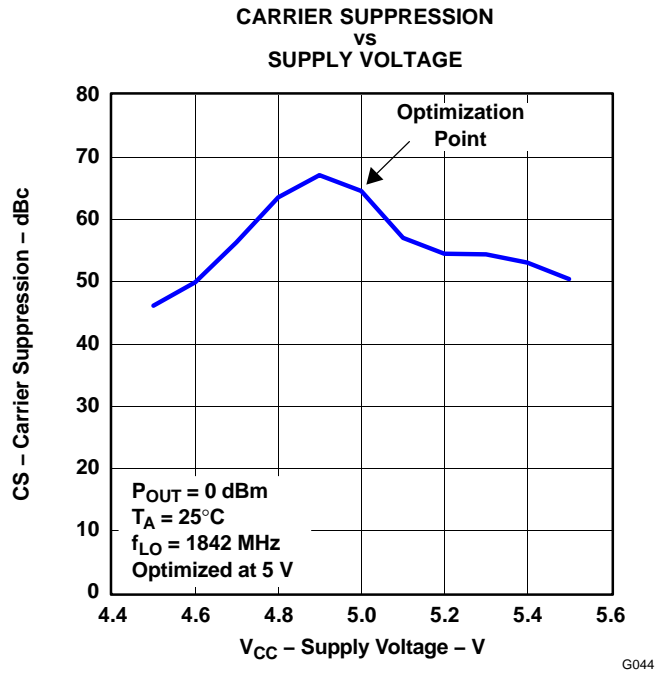


Figure 19.

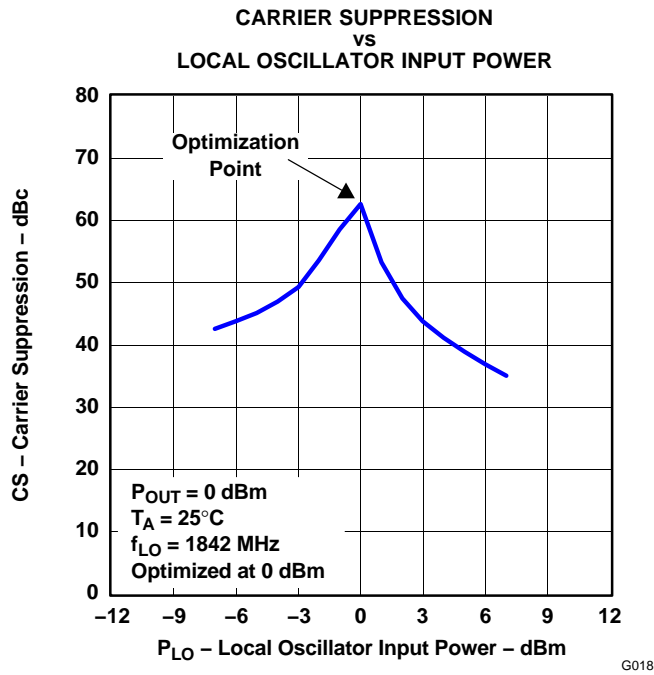


Figure 20.

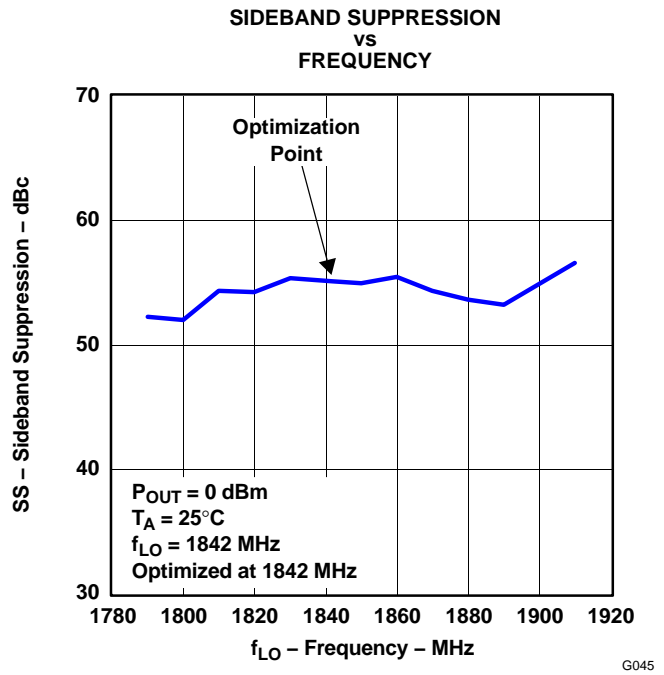


Figure 21.

TYPICAL CHARACTERISTICS (continued)

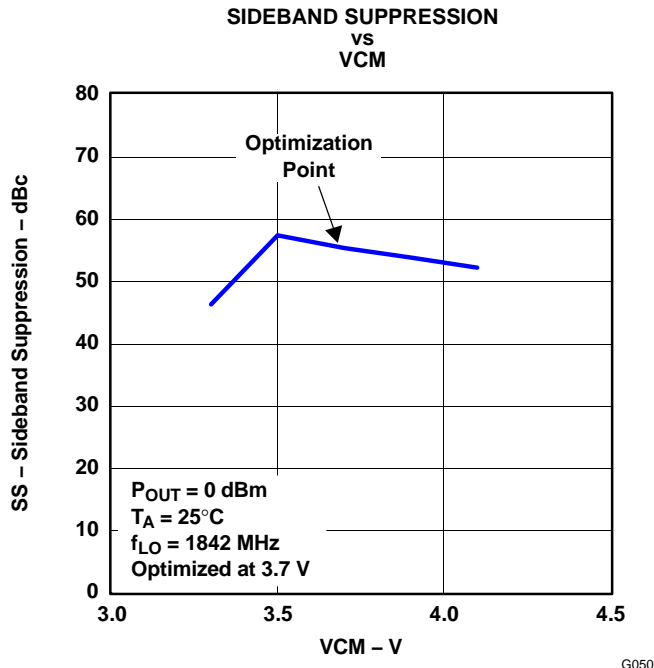


Figure 22.

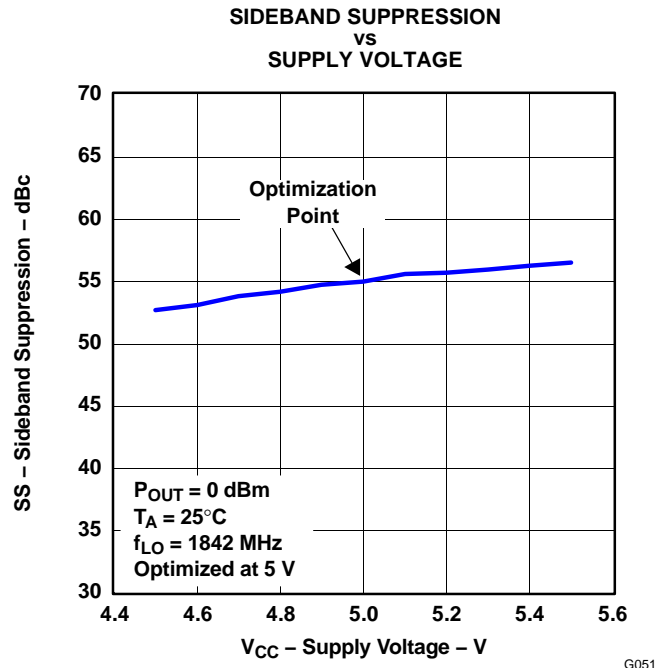


Figure 23.

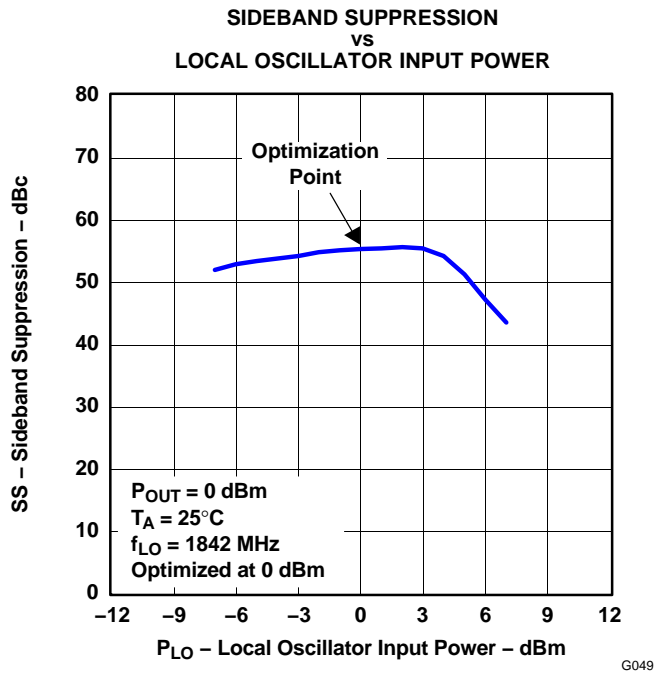


Figure 24.

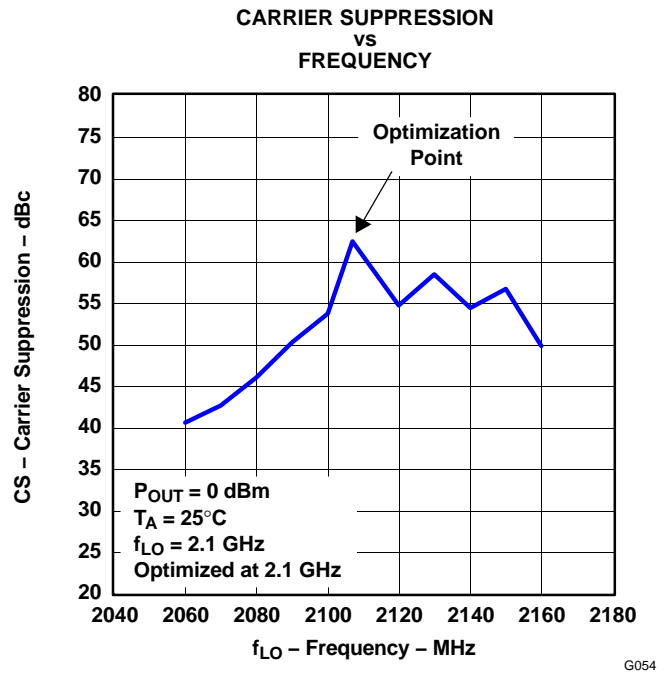


Figure 25.

TYPICAL CHARACTERISTICS (continued)

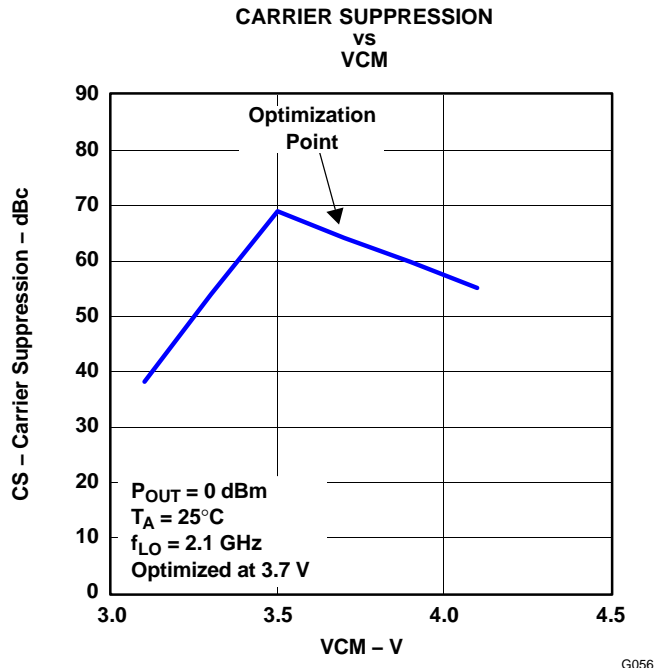


Figure 26.

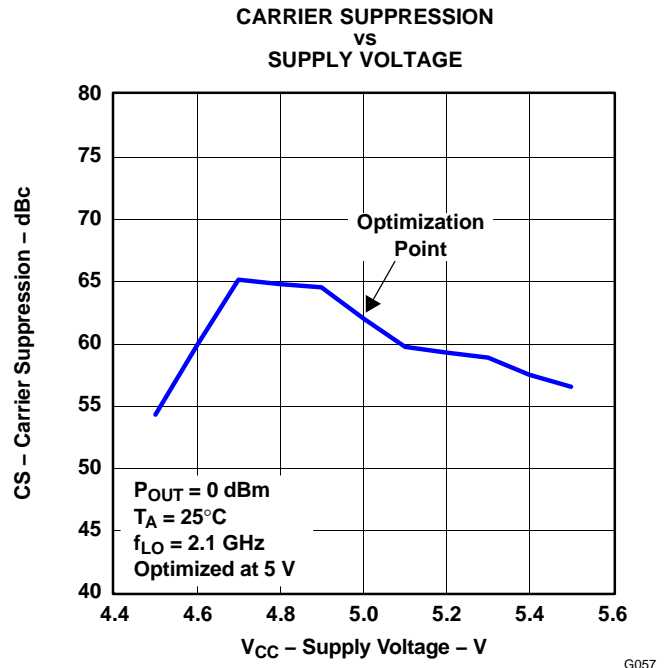


Figure 27.

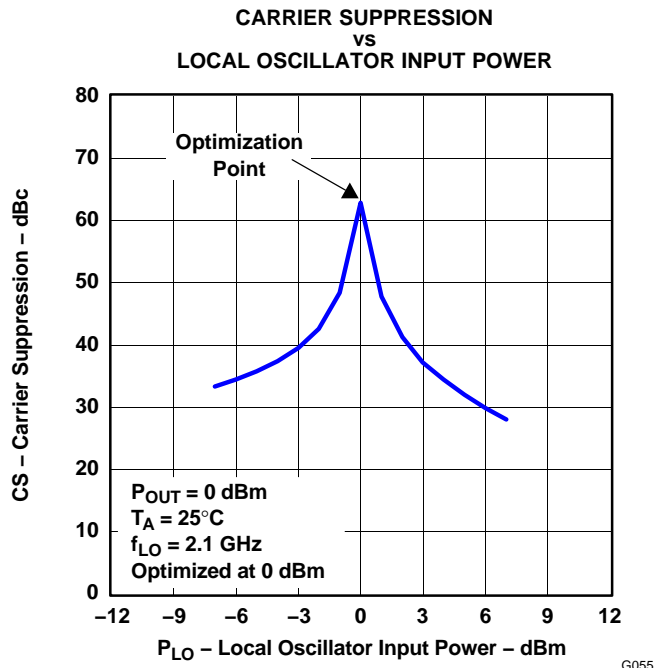


Figure 28.

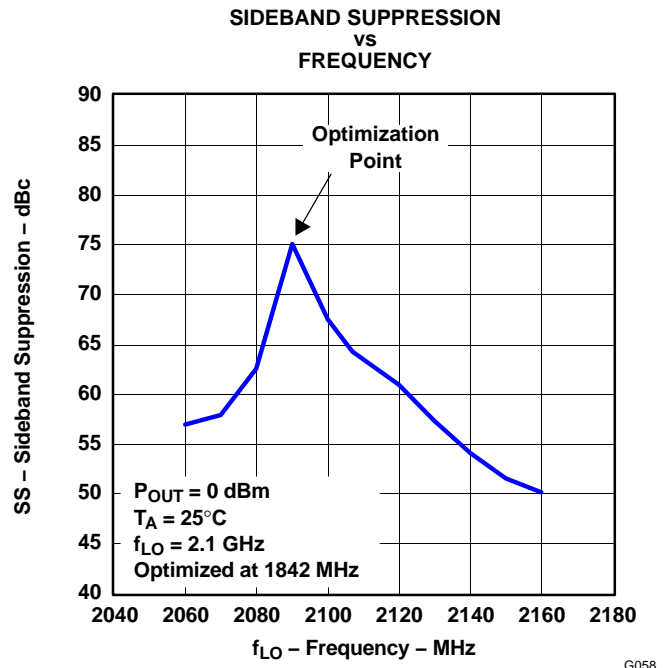


Figure 29.

TYPICAL CHARACTERISTICS (continued)

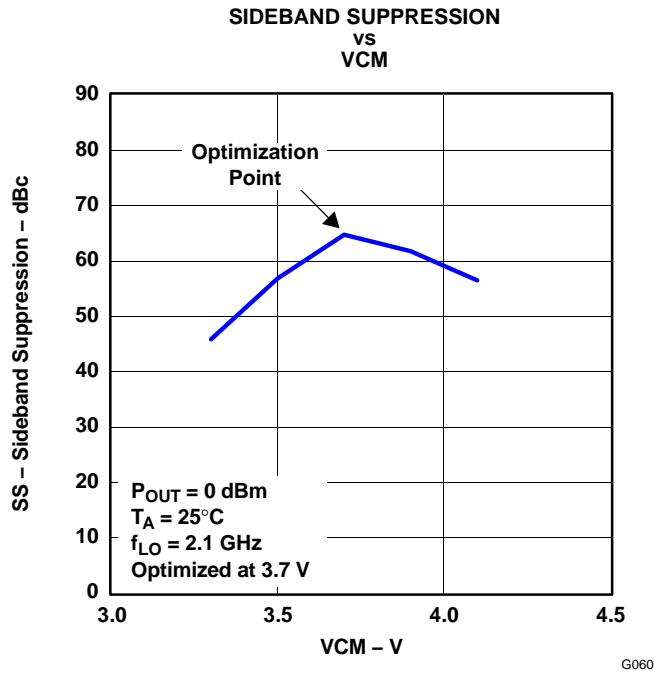


Figure 30.

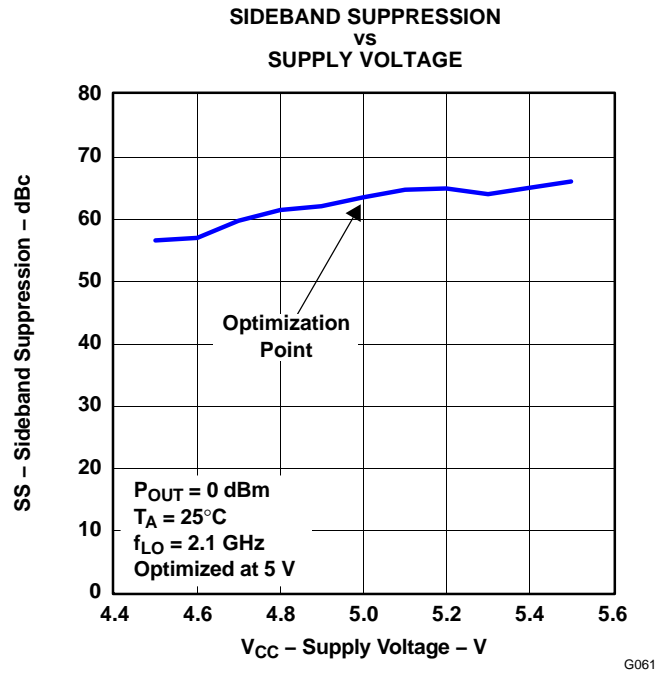


Figure 31.

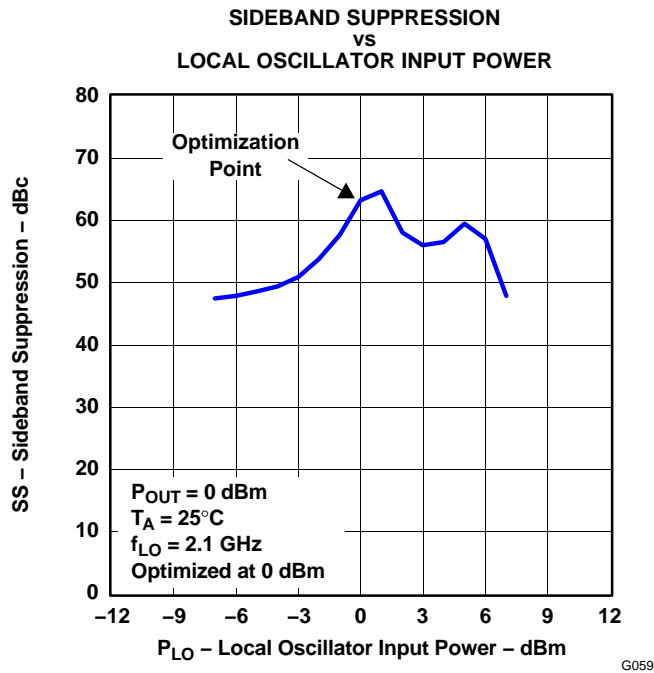


Figure 32.

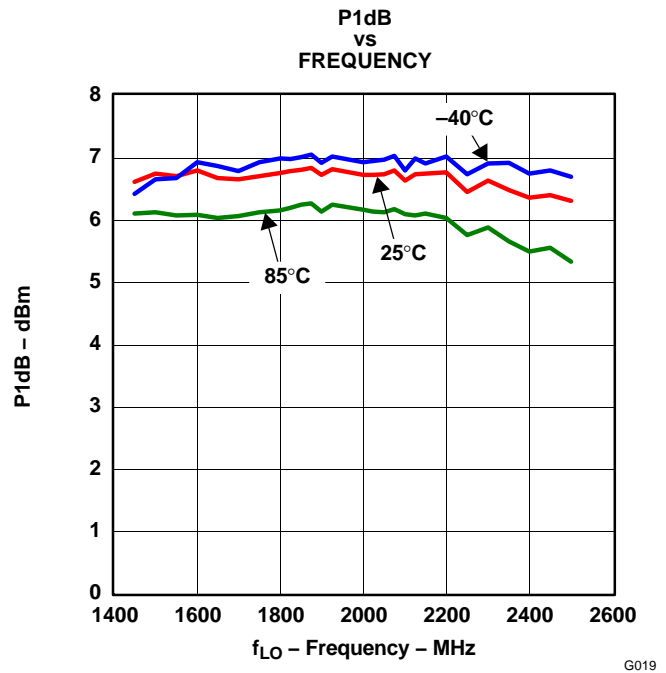


Figure 33.

TYPICAL CHARACTERISTICS (continued)

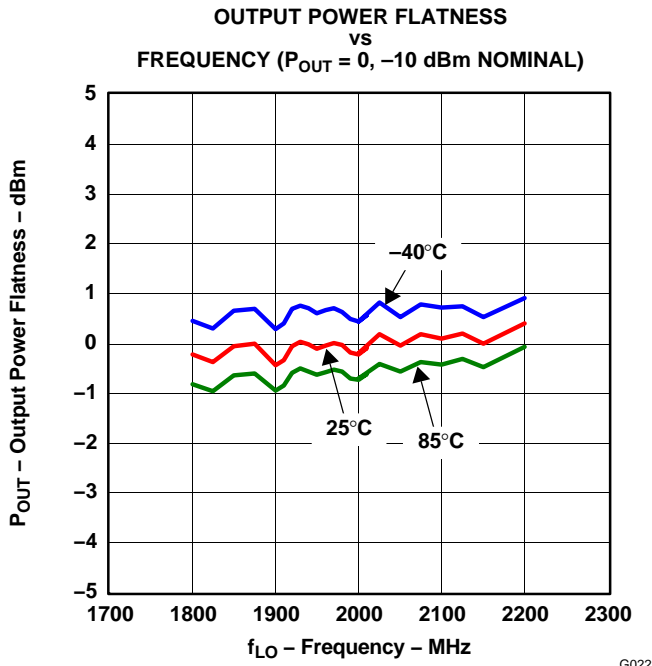


Figure 34.

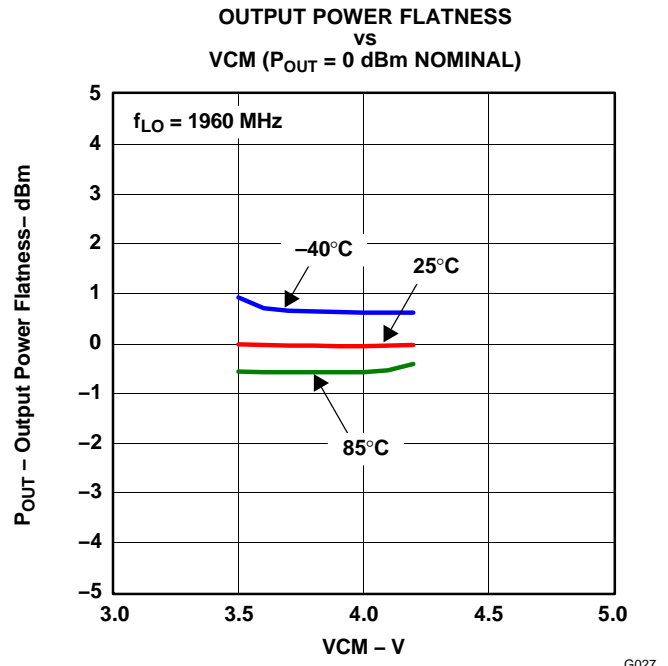


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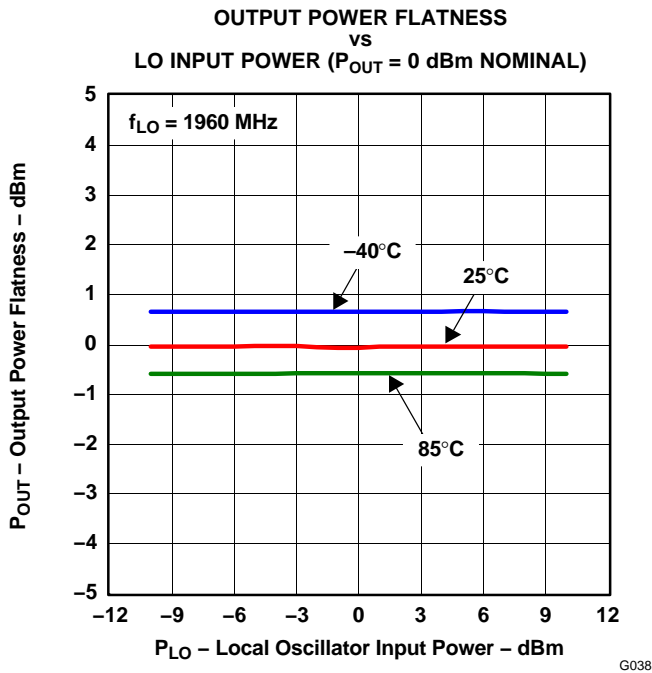


Figure 36.

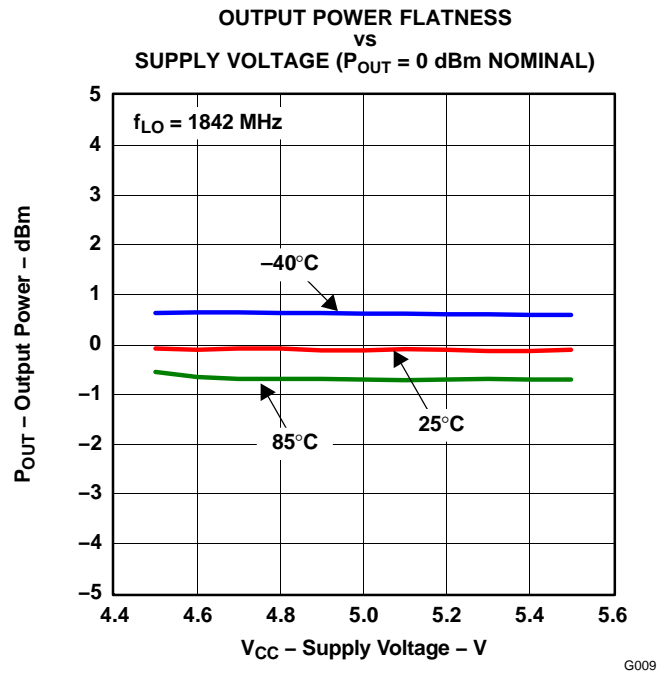


Figure 37.

TYPICAL CHARACTERISTICS (continued)

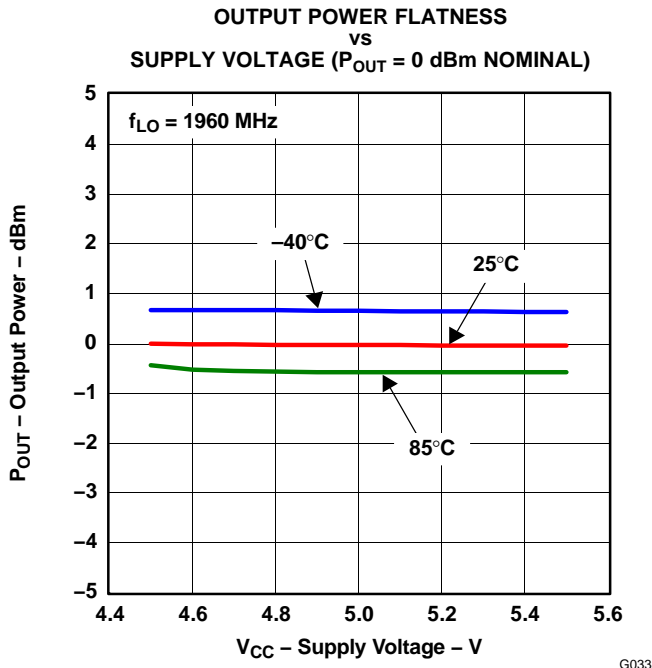


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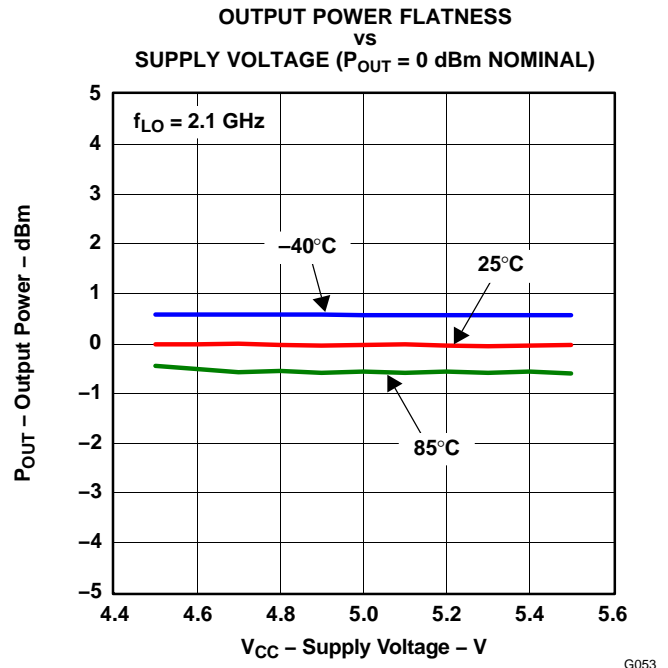


Figure 39.

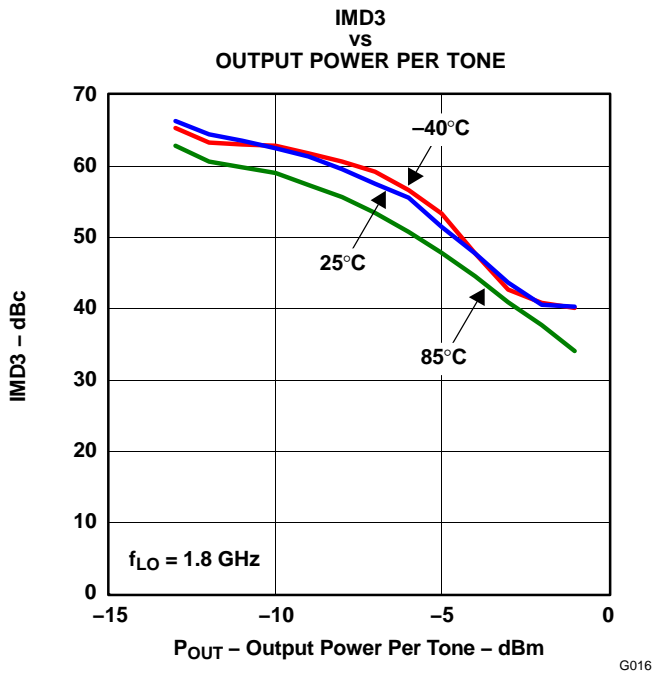


Figure 40.

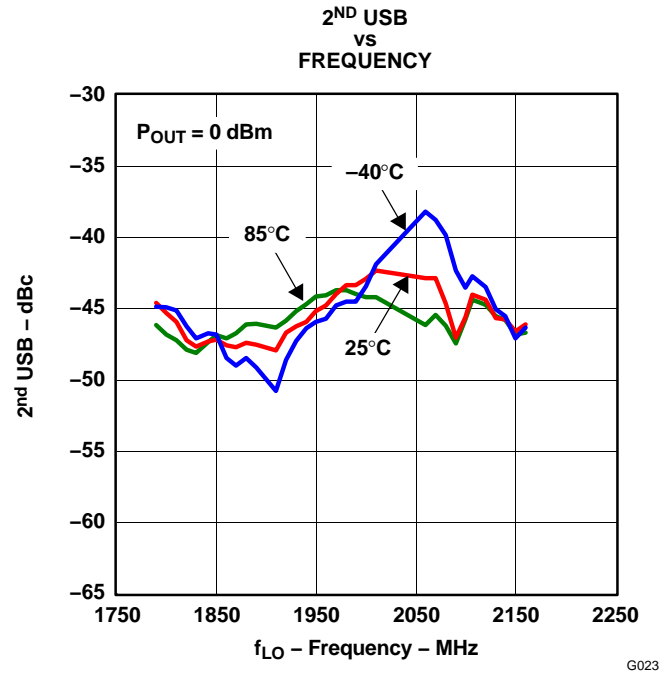


Figure 41.

TYPICAL CHARACTERISTICS (continued)

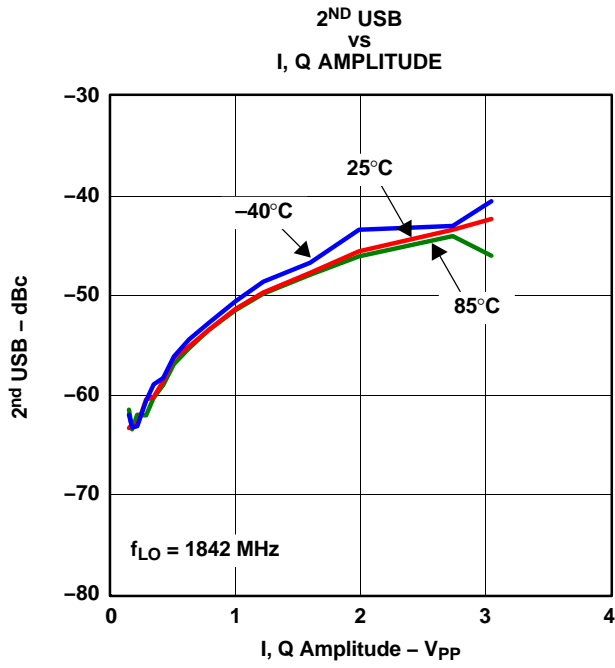


Figure 42.

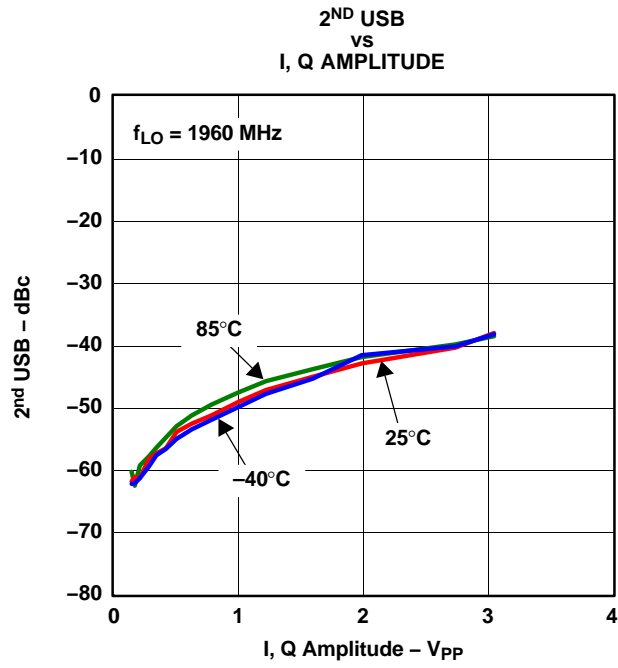


Figure 43.

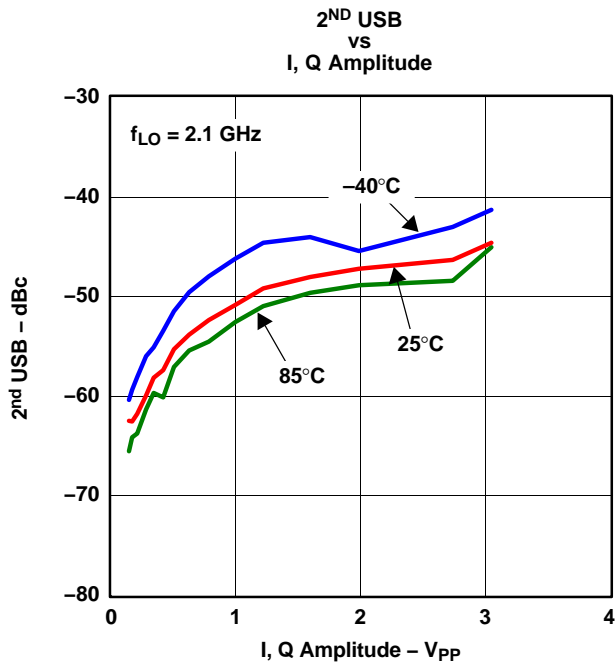


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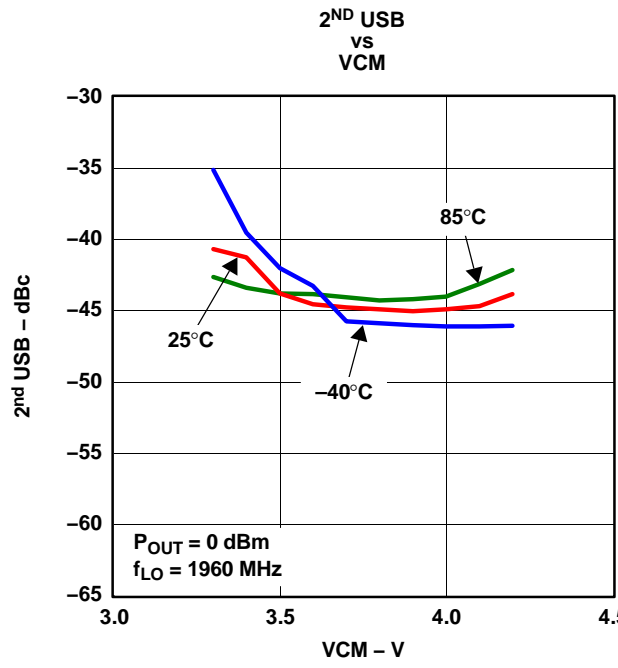


Figure 45.

TYPICAL CHARACTERISTICS (continued)

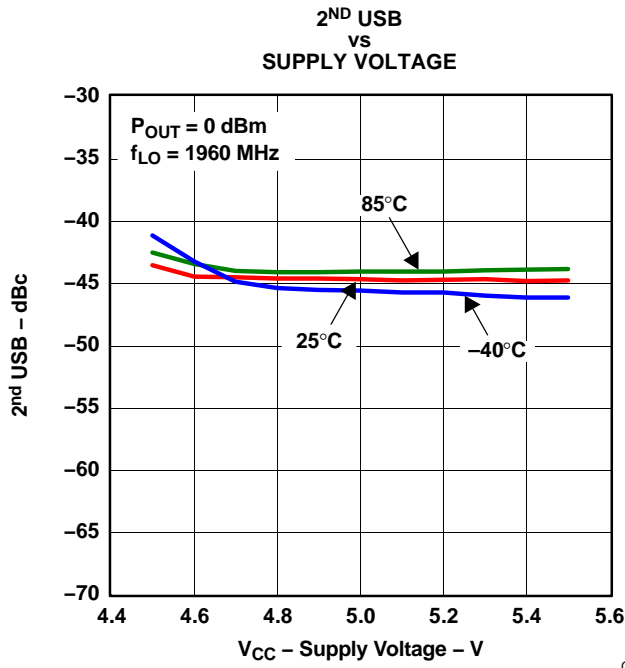


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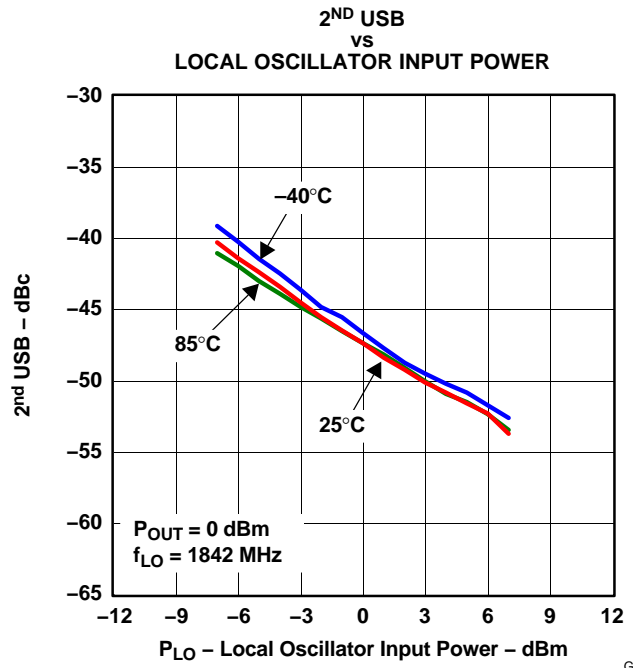


Figure 47.

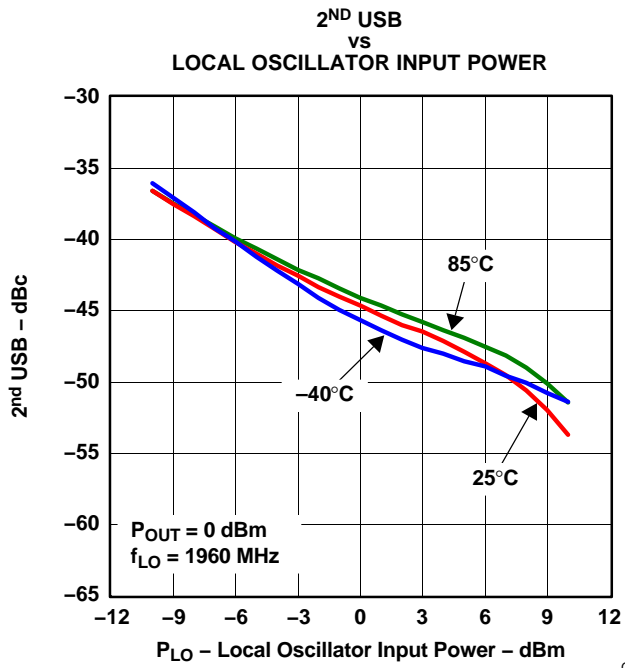


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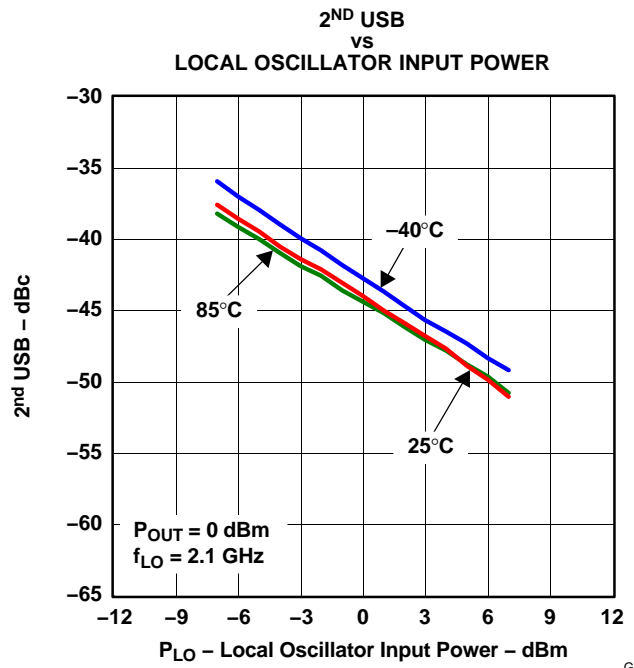


Figure 49.

TYPICAL CHARACTERISTICS (continued)

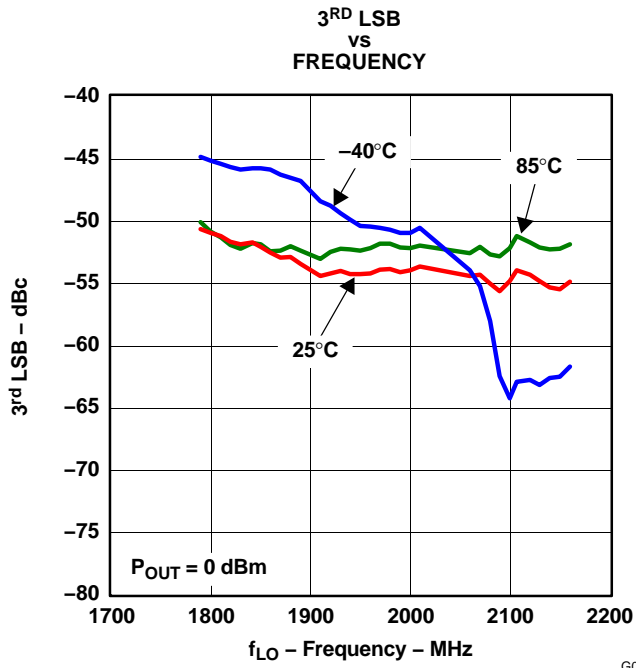


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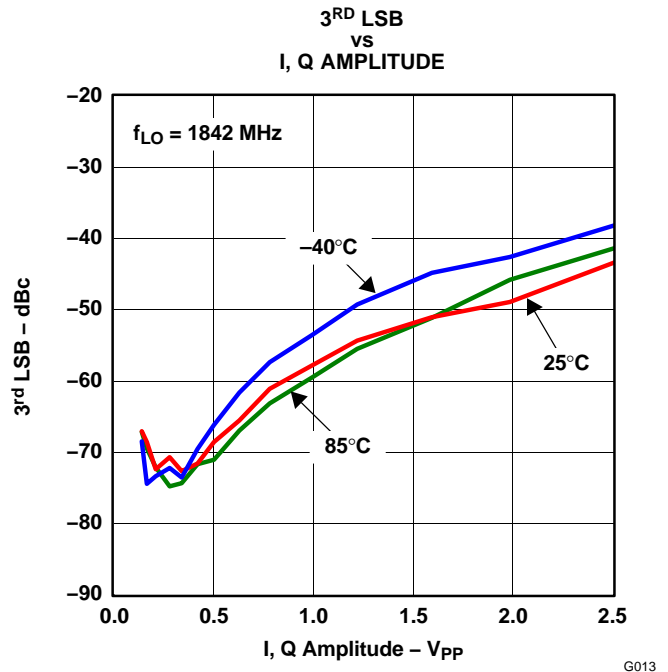


Figure 51.

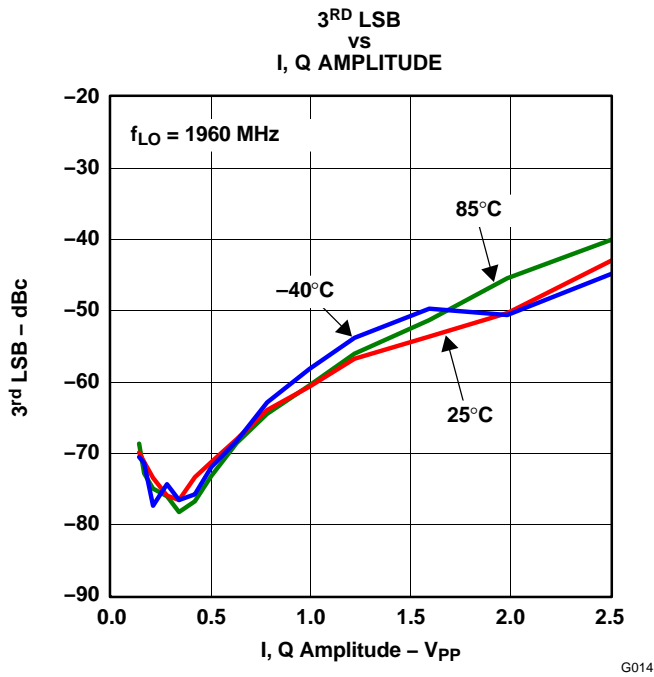


Figure 52.

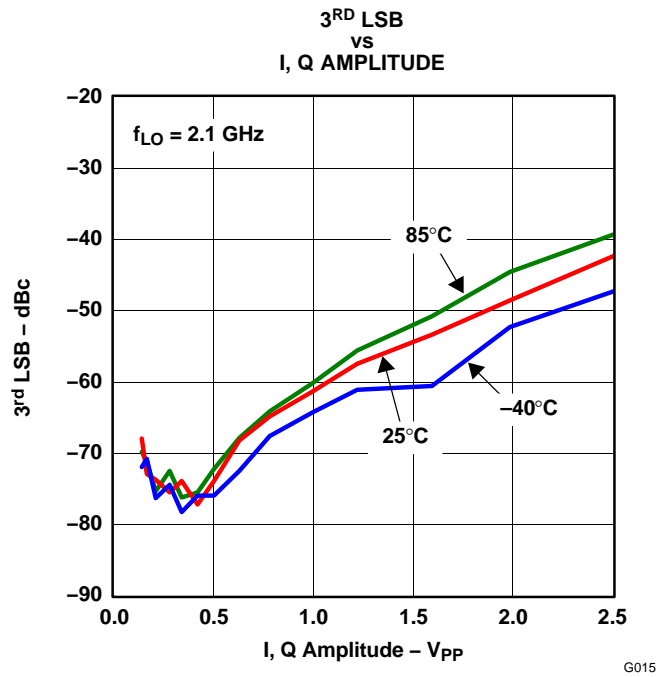


Figure 53.

TYPICAL CHARACTERISTICS (continued)

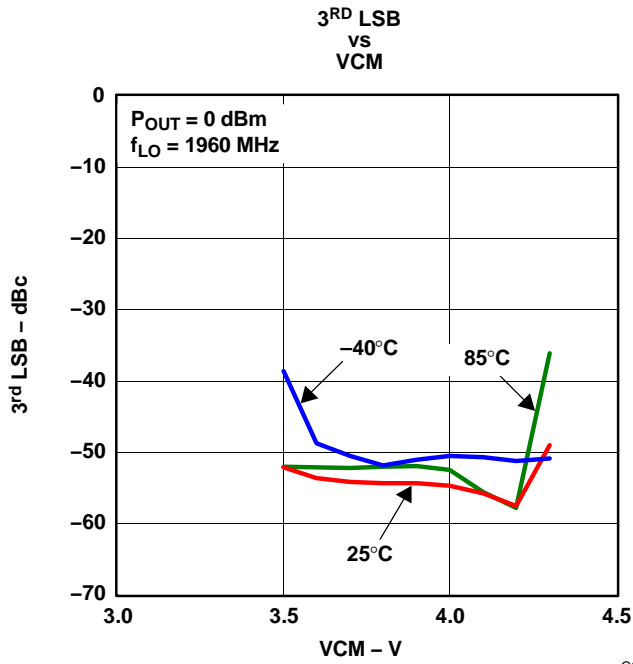


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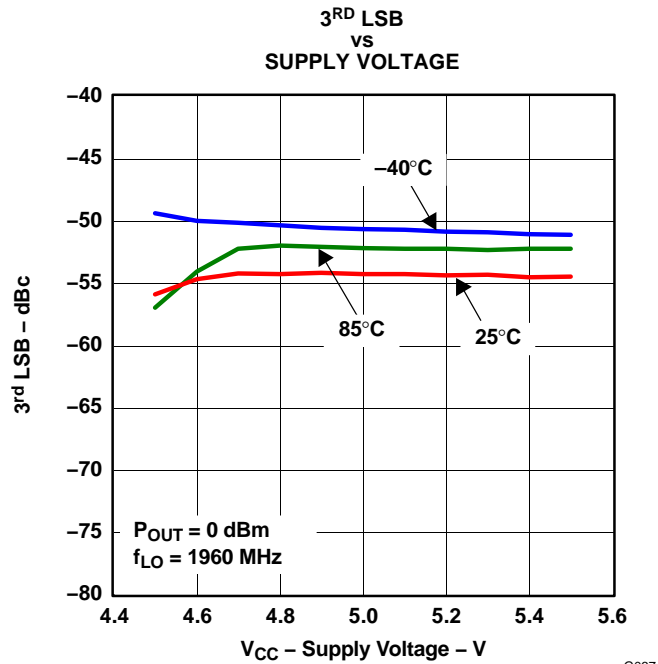


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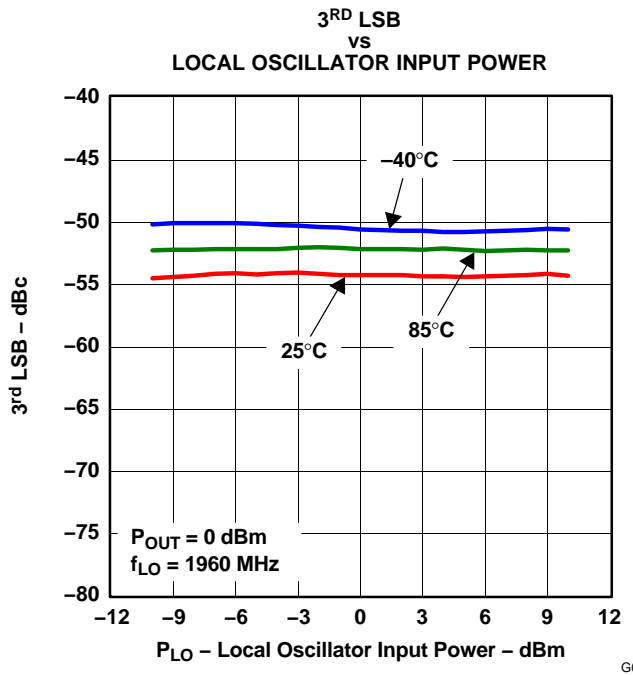


Figure 56.

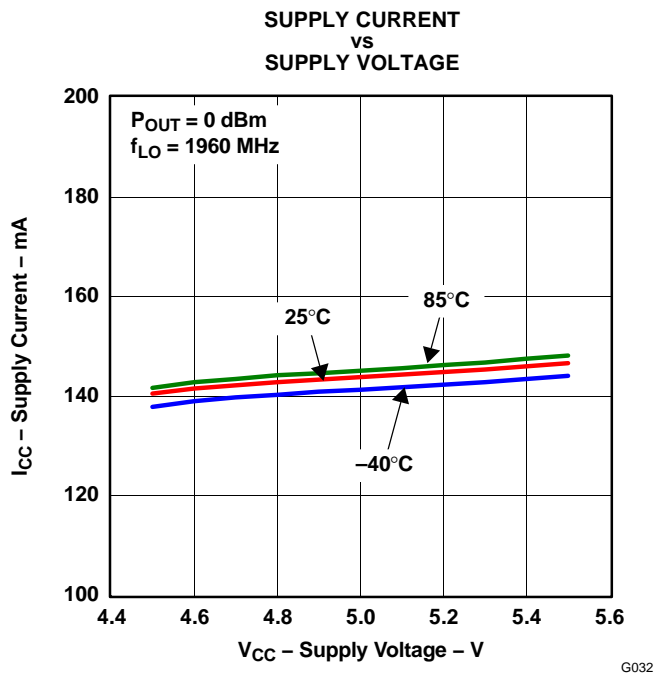


Figure 57.

TYPICAL CHARACTERISTICS (continued)

NOISE AT 6 MHz OFFSET
vs
OUTPUT POWER

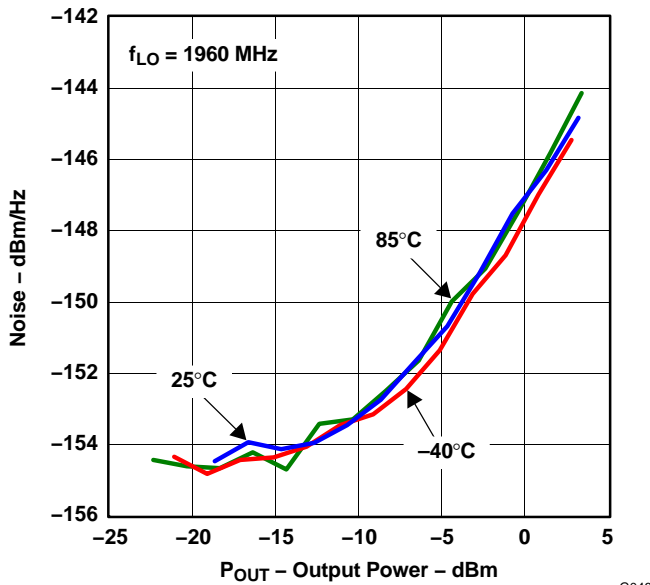


Figure 58.

G046

NOISE AT 60-MHz OFFSET
vs
OUTPUT POWER

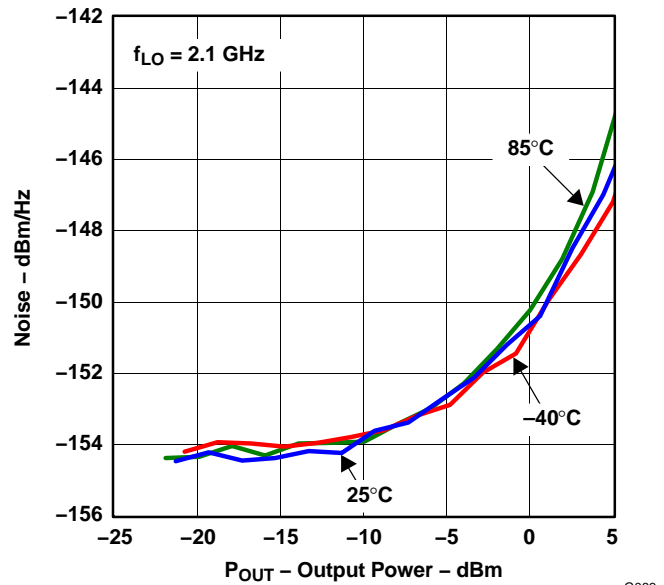


Figure 59.

G063

NOISE DISTRIBUTION AT 6-MHz
OFFSET OVER TEMPERATURE

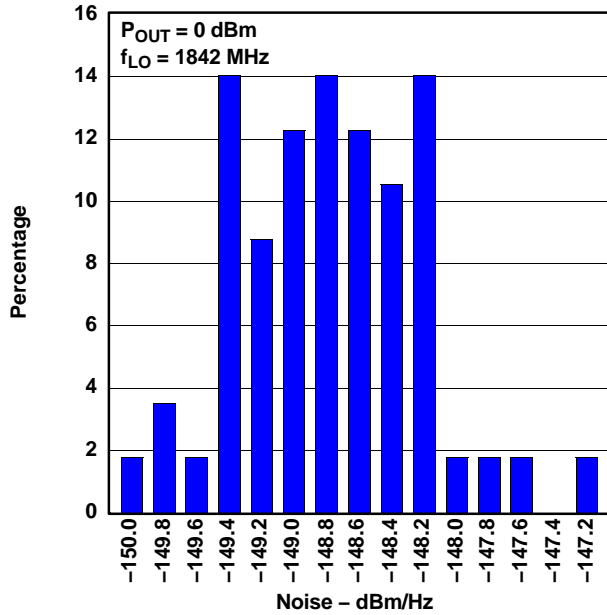


Figure 60.

G065

NOISE DISTRIBUTION AT 6-MHz
OFFSET OVER TEMPERATURE

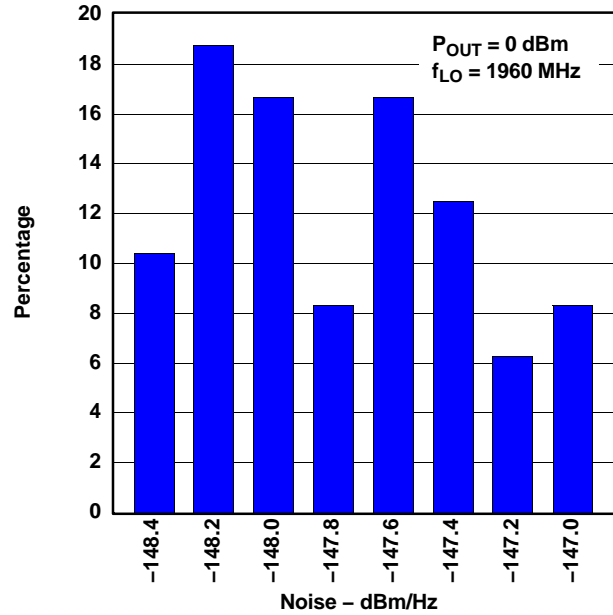
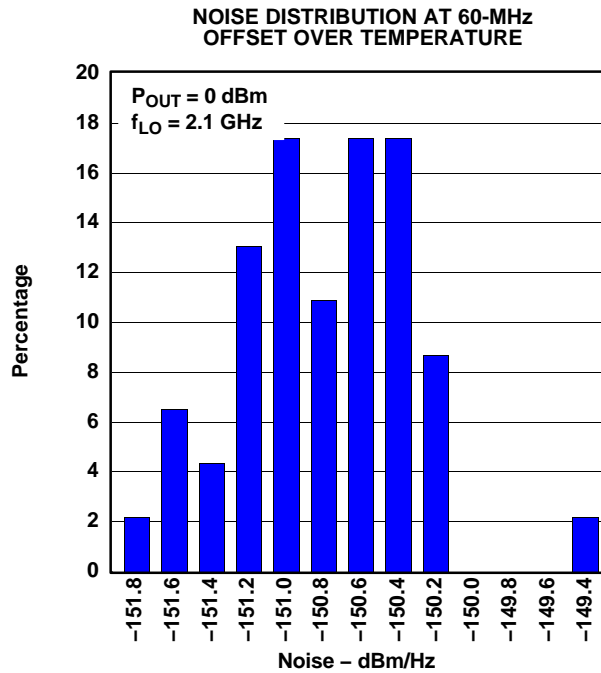


Figure 61.

G064

TYPICAL CHARACTERISTICS (continued)



G066

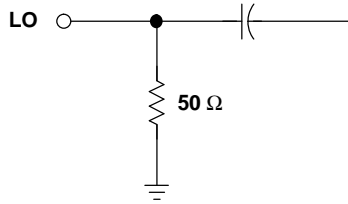
Figure 62.

THEORY OF OPERATION

The TRF3702 employs a double-balanced mixer architecture in implementing the direct I, Q upconversion. The I, Q inputs can be driven single-endedly or differentially, with comparable performance in both cases. The common mode level (VCM) of the four inputs (IVIN, IREF, QVIN, QREF) is typically set to 3.7 V and needs to be driven externally. These inputs go through a set of differential amplifiers and through a V-I converter to feed the double-balanced mixers. The AC-coupled LO input to the device goes through a phase splitter to provide the in-phase and quadrature signals that in turn drive the mixers. The outputs of the mixers are then summed, converted to single-ended signals, and amplified before they are fed to the output port RFOUT. The output of the TRF3702 is ac-coupled and can drive 50-Ω loads.

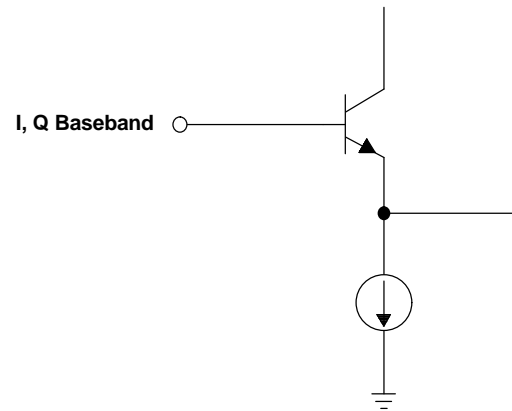
EQUIVALENT CIRCUITS

Figure 63 through Figure 66 show equivalent schematics for the main inputs and outputs of the device.



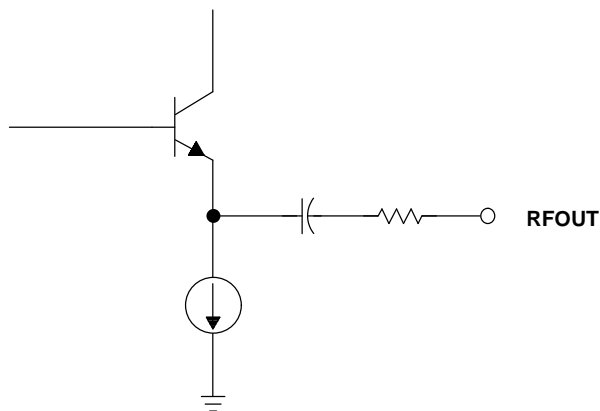
S0001-01

Figure 63. LO Equivalent Input Circuit



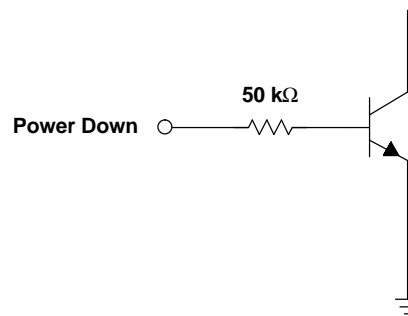
S0002-01

Figure 64. IVIN, QVIN, IREF, QREF Equivalent Circuit



S0003-01

Figure 65. RFOUT Equivalent Circuit



S0004-01

Figure 66. Power-Down (PWD) Equivalent Circuit

APPLICATION INFORMATION

DRIVING THE I, Q INPUTS

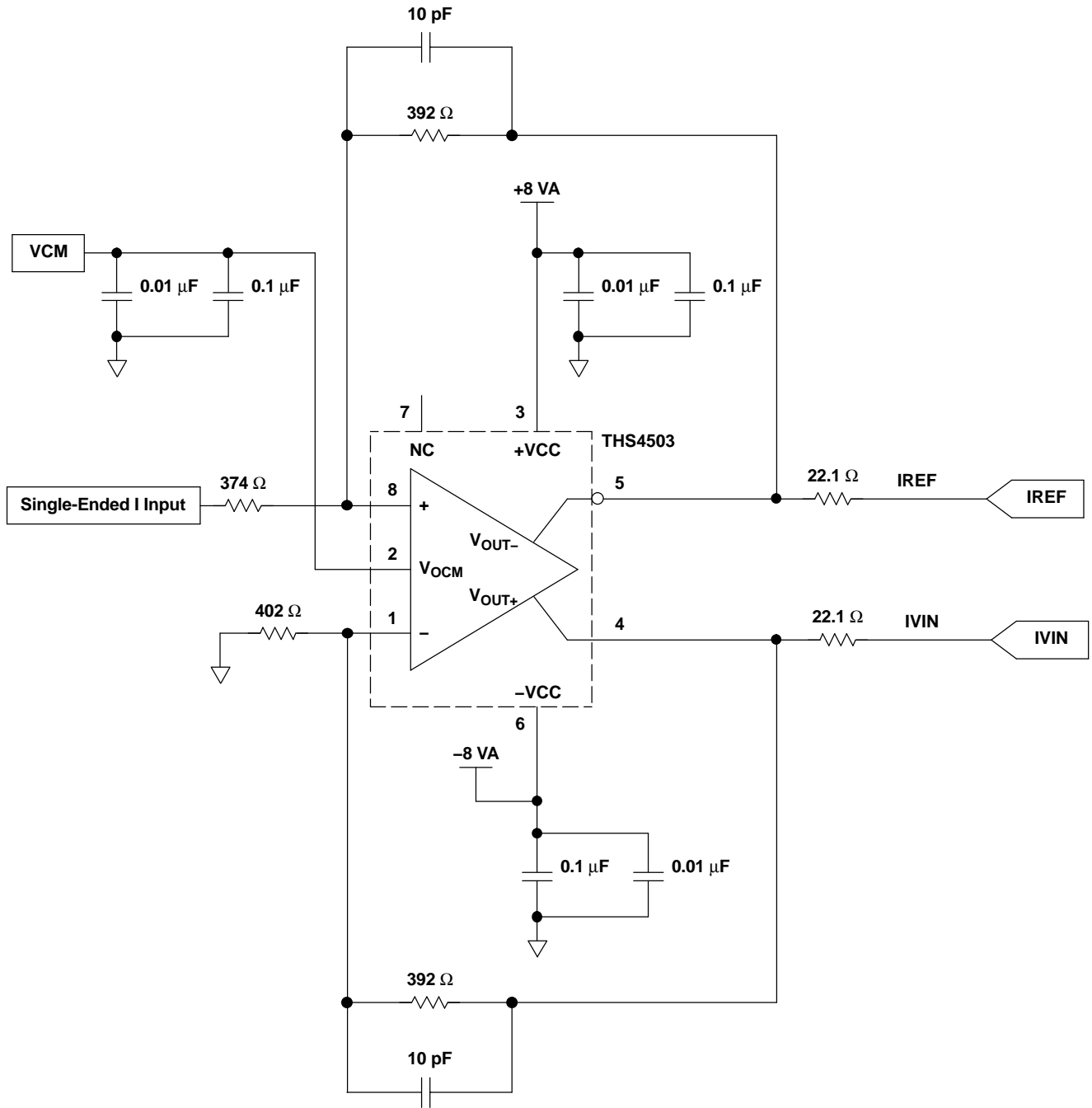
There are several ways to drive the four baseband inputs of the TRF3702 to the required amplitude and dc offset. The optimal configuration depends on the end application requirements and the signal levels desired by the designer.

The TRF3702 is by design a differential part, meaning that ideally the user should provide fully complementary signals. However, similar performance in every respect can be achieved if the user only has single-ended signals available. In this case, the IREF and QREF pins just need to have the VCM dc offset applied.

Implementing a Single-to-Differential Conversion for the I, Q inputs

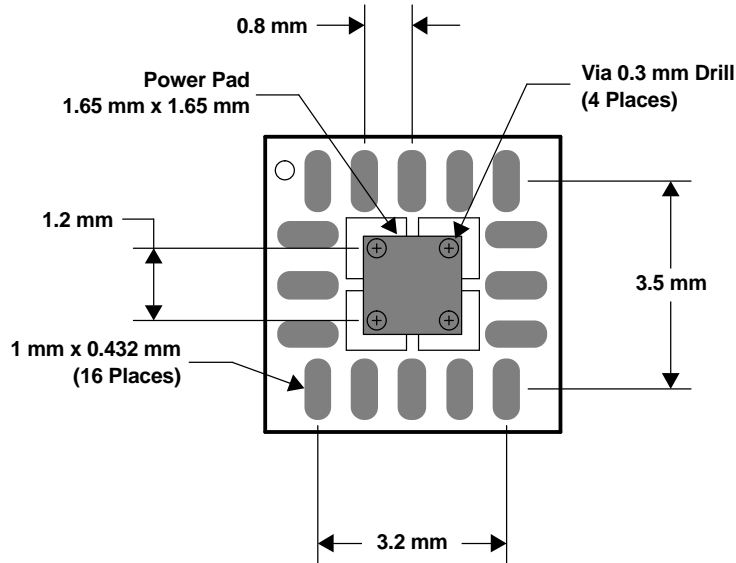
In case differential I, Q signals are desired but not available, the THS4503 family of wideband, low-distortion, fully differential amplifiers can be used to provide a convenient way of performing this conversion. Even if differential signals are available, the THS4503 can provide gain in case a higher voltage swing is required. Besides featuring high bandwidth and high linearity, the THS4503 also provides a convenient way of applying the VCM to all four inputs to the modulator through the VOVM pin (pin 2). The user can further adjust the dc levels for optimum carrier suppression by injecting extra dc at the inputs to the operational amplifier, or by individually adding it to the four outputs. Figure 67 shows a typical implementation of the THS4503 as a driver for the TRF3702. Gain can be easily incorporated in the loop by adjusting the feedback resistors appropriately. For more details, see the THS4503 data sheet at www.ti.com.

APPLICATION INFORMATION (continued)



S0005-02

Figure 67. Using the THS4503 to Condition the Baseband Inputs to the TRF3702 (I Channel Shown)

APPLICATION INFORMATION (continued)

M0002-01

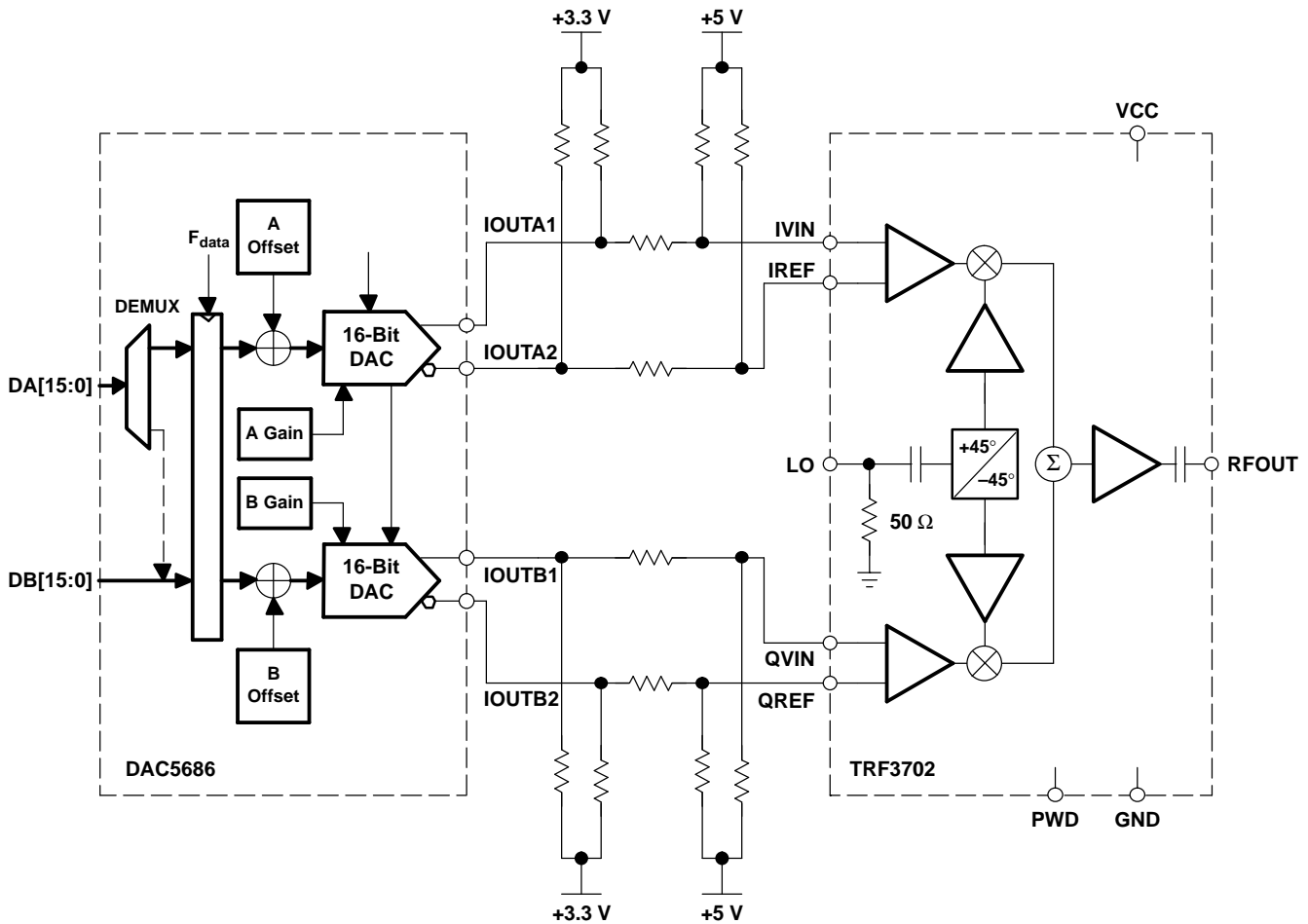
Figure 69. Board Layout for the TRF3702 Device**IMPLEMENTING A DIRECT UPCONVERSION TRANSMITTER USING A TI DAC**

The TRF3702 is ideal for implementing a direct upconversion transmitter, where the input I, Q data can originate from an ASIC or a DAC. Texas Instruments' line of digital-to-analog converters (DAC) is ideally suited for interfacing to the TRF3702. Such DACs include, among others, the DAC290x series, DAC5672, and DAC5686.

This section illustrates the use of the DAC5686, which offers a unique set of features that make interfacing to the TRF3702 easy and convenient. The DAC5686 is a 16-bit, 500 MSPS, $2\times-16\times$ interpolating dual-channel DAC, and it features I, Q adjustments for optimal interface to the TRF3702. User-selectable, 11-bit offset and 12-bit gain adjustments can optimize the carrier and sideband suppression of the modulator, resulting in enhanced performance and relaxed filtering requirements at RF. The preferred mode of operation of the DAC5686 for direct interface with the TRF3702 at baseband is the dual-DAC mode. The user also has the flexibility of selecting any one of the four possible complex spectral bands to be fed into the TRF3702. For details on the available modes and programming, see the DAC5686 data sheet available at www.ti.com.

Figure 70 shows the DAC5686 in dual-DAC mode, which is best-suited for zero-IF interface to the TRF3702. In this mode, a seamless, passive interface between the DAC output and the input to the modulator is used, so that no extra components are needed between the two devices. The optimum dc offset level for the inputs to the TRF3702 (VCM) is approximately 3.7 V. The output of the DAC should be centered around 3.3 V or less (depending on signal swing), in order to ensure that its output compliance limits are not exceeded. The resistive network shown in Figure 70 allows for this dc offset transition while still providing a dc path between the DAC output and the modulator. This ensures that the dc offset adjustments on the DAC5686 can still be applied to optimize the carrier suppression at the modulator output. The combination of the DAC5686 and the TRF3702 provides a unique signal-chain solution with state-of-the-art performance for wireless infrastructure applications.

APPLICATION INFORMATION (continued)

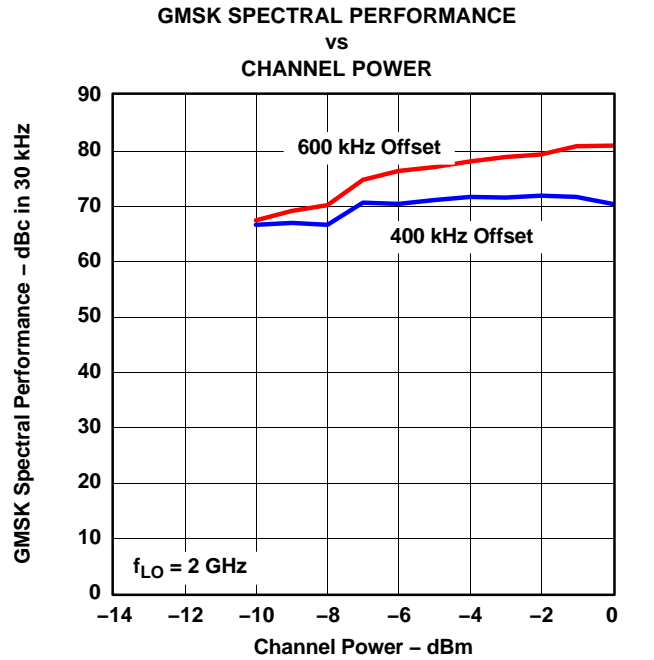


S0010-02

Figure 70. DAC5686 in Dual-DAC Mode With Quadrature Modulator

GSM Applications

The TRF3702 is ideally suited for GSM applications, because it combines high linearity with very low noise levels. Figure 60 and Figure 61 show the distribution of noise vs output power for the TRF3702 over the entire recommended temperature range. The level of noise attained in combination with the superior IMD3 performance shown in Figure 40 means that the user can reach superior levels of C/N while maintaining high linearity. This combination offers the capability of delivering very low levels of EVM, meeting the stringent requirements imposed by the GSM/EDGE standards. Figure 71 shows the spectral mask compliance for the device versus channel power, for both 400-kHz and 600-kHz offsets.

APPLICATION INFORMATION (continued)**WCDMA Applications**

The TRF3702 is also optimized for WCDMA applications, where both adjacent-channel power ratio (ACPR) and noise density are critically important. Figure 62 shows the noise performance of the modulator at a 60-MHz offset over temperature. In addition, Figure 72 shows the 60-MHz offset noise measured at the output of the TRF3702 versus WCDMA channel power. Using Texas Instruments' DAC568x series of high-performance digital-to-analog converters in the configuration depicted in Figure 70, state-of-the-art levels of ACPR have been measured. In each case, test model 1 was used with 64 active channels as the baseband input to the TRF3702. Figure 73 shows the performance attained for a single WCDMA carrier at 2.14 GHz, with a measured ACPR of 71.2 dBc for a channel power of -14 dBm. This unprecedented level of ACPR in conjunction with the very low levels of noise at 60-MHz offset make the TRF3702 an optimum choice for such applications. Figure 74 shows the single-carrier WCDMA ACPR performance versus channel power; it is important to note that even at very high output power levels, the TRF3702 maintains great linearity, offering 64 dBc of ACPR at an output-channel power of -8 dBm.

APPLICATION INFORMATION (continued)

NOISE AT 60-MHz OFFSET
vs
WCDMA CHANNEL POWER

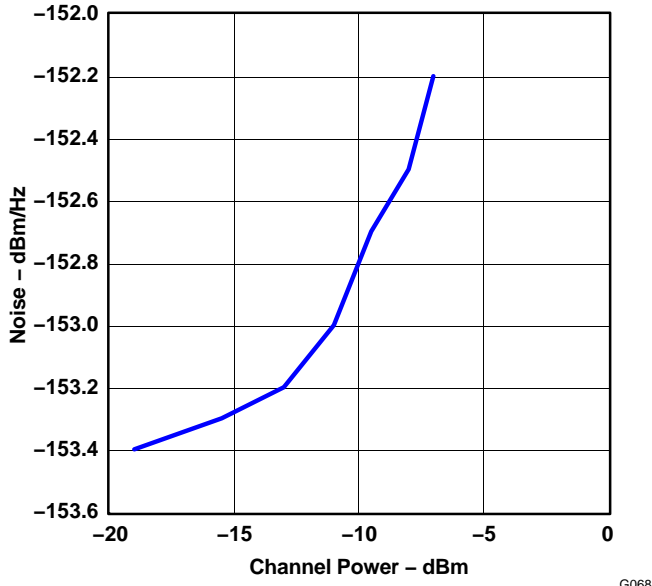


Figure 72.

SINGLE-CARRIER WCDMA PERFORMANCE

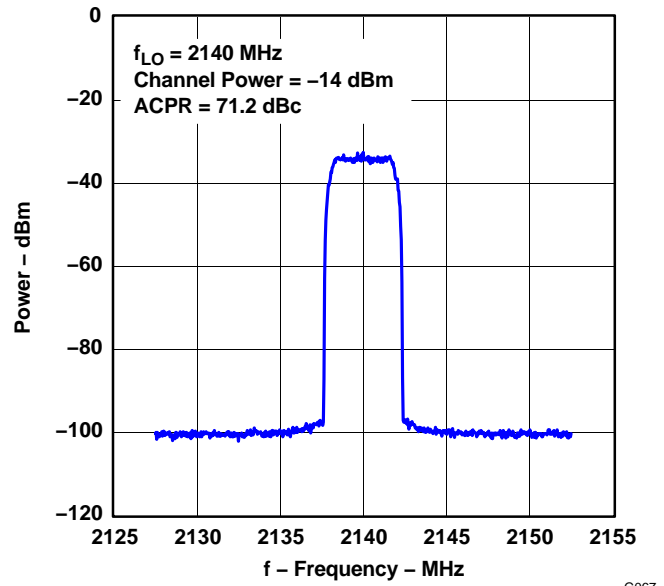


Figure 73.

SINGLE-CARRIER WCDMA ACPR
vs
CHANNEL POWER

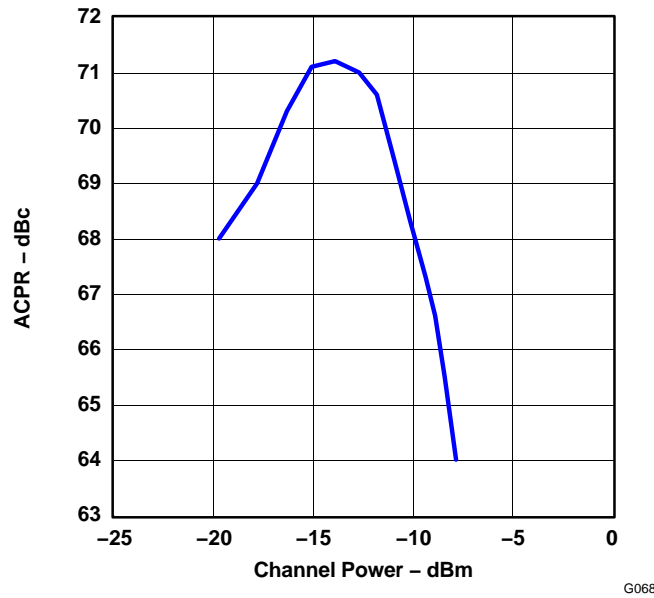


Figure 74.

APPLICATION INFORMATION (continued)

The TRF3702 can also be used for multicarrier applications, as is illustrated in Figure 75. For a 4-carrier case at a total output power of -16.7 dBm, an ACPR of almost 63 dBc can be reached. Figure 76 shows the ACPR profile for a 4-carrier WCDMA application versus per-carrier channel power. Further improvements in performance can be achieved by including a low-pass filter between the output of the DAC and the input to the TRF3702, based upon the frequency planning and specific requirements of a given design. The combination of the TRF3702, the DAC568x, and the TRF3750 provides a unique signal-chain chipset capable of delivering state-of-the-art levels of performance for the most challenging WCDMA applications.

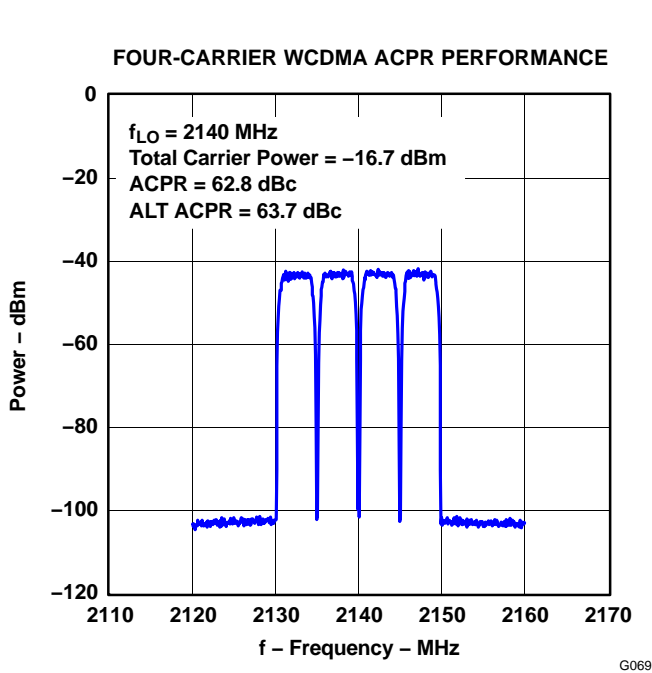


Figure 75.

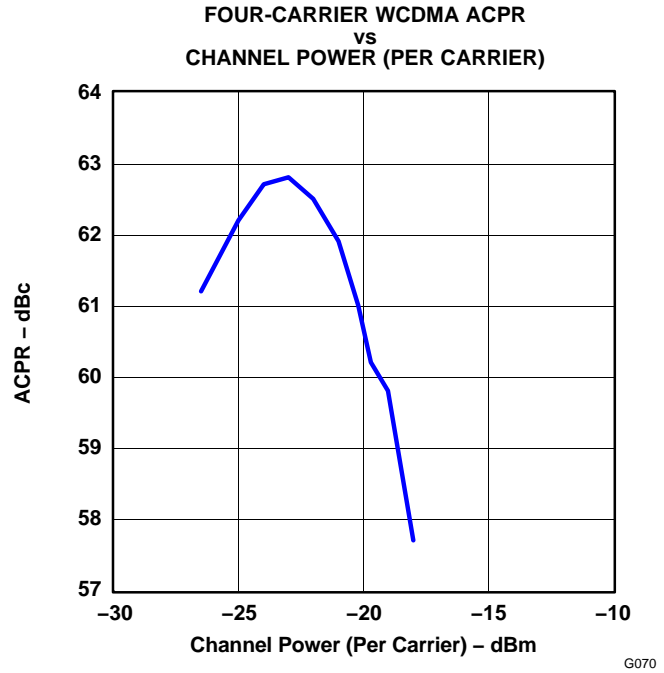
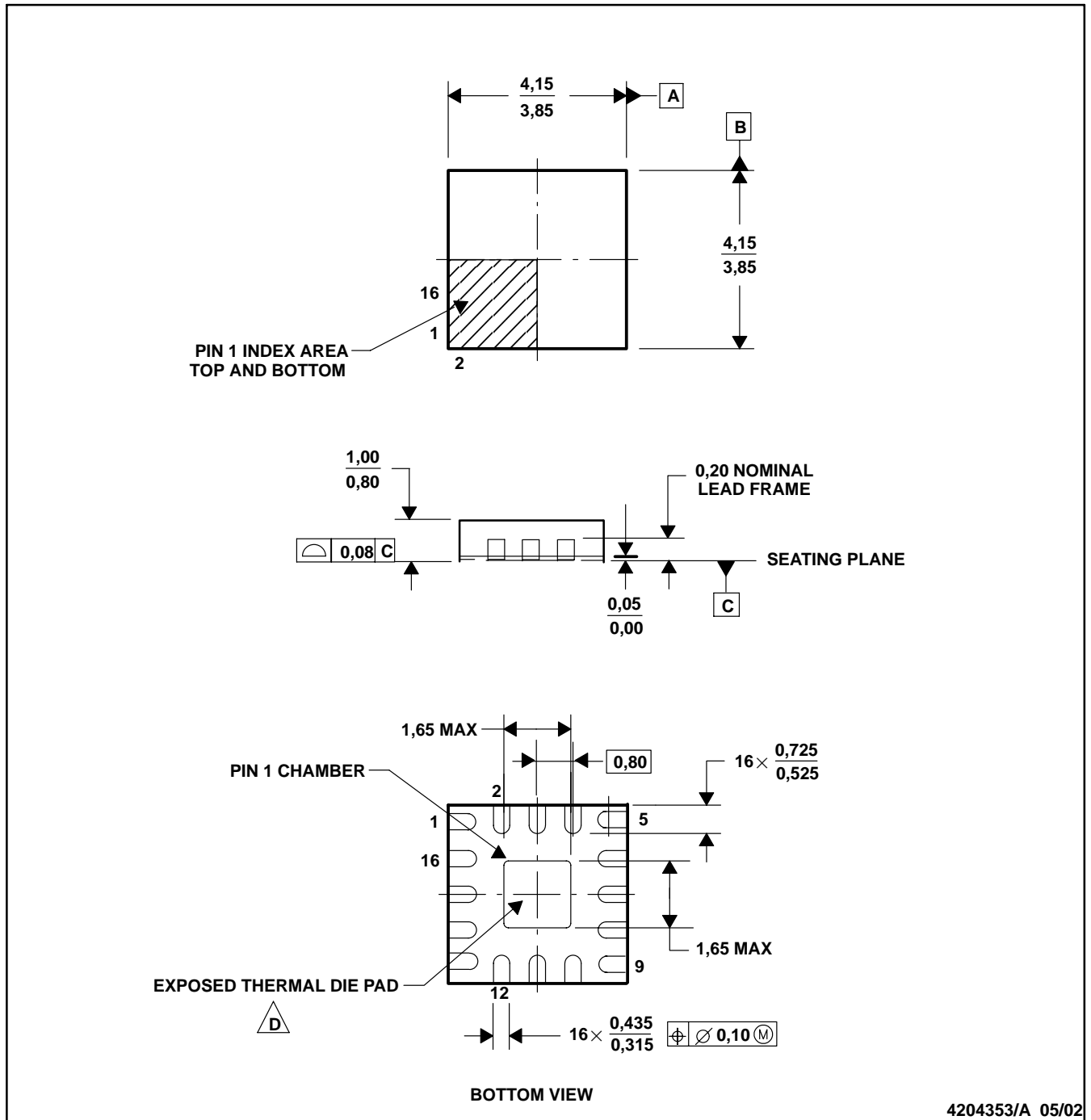



Figure 76.

RHC (S-PQFP-N16)

(CUSTOM PACKAGE)

PLASTIC QUAD FLATPACK



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. QFN (Quad Flatpack No-Lead) Package configuration.
 -  D. The Package thermal performance may be enhanced by bonding the thermal die pad to an external thermal plane. This pad is electrically and thermally connected to the backside of the die and possibly selected ground leads.

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